

FIG. 1

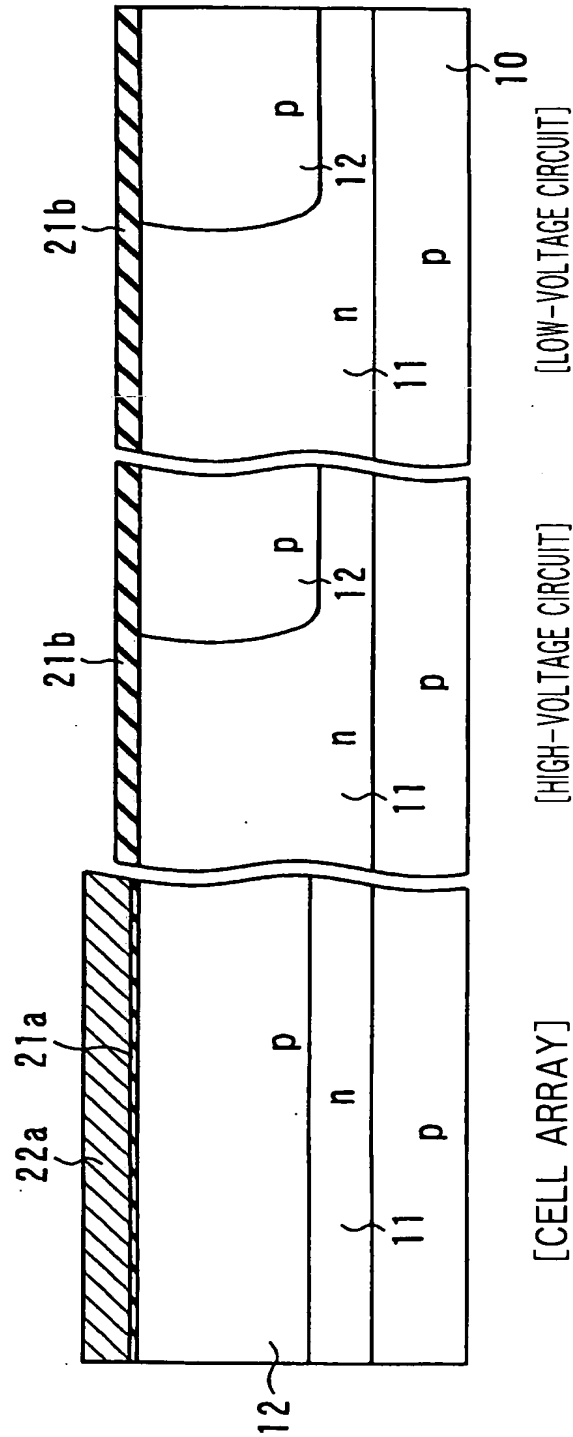


FIG. 2

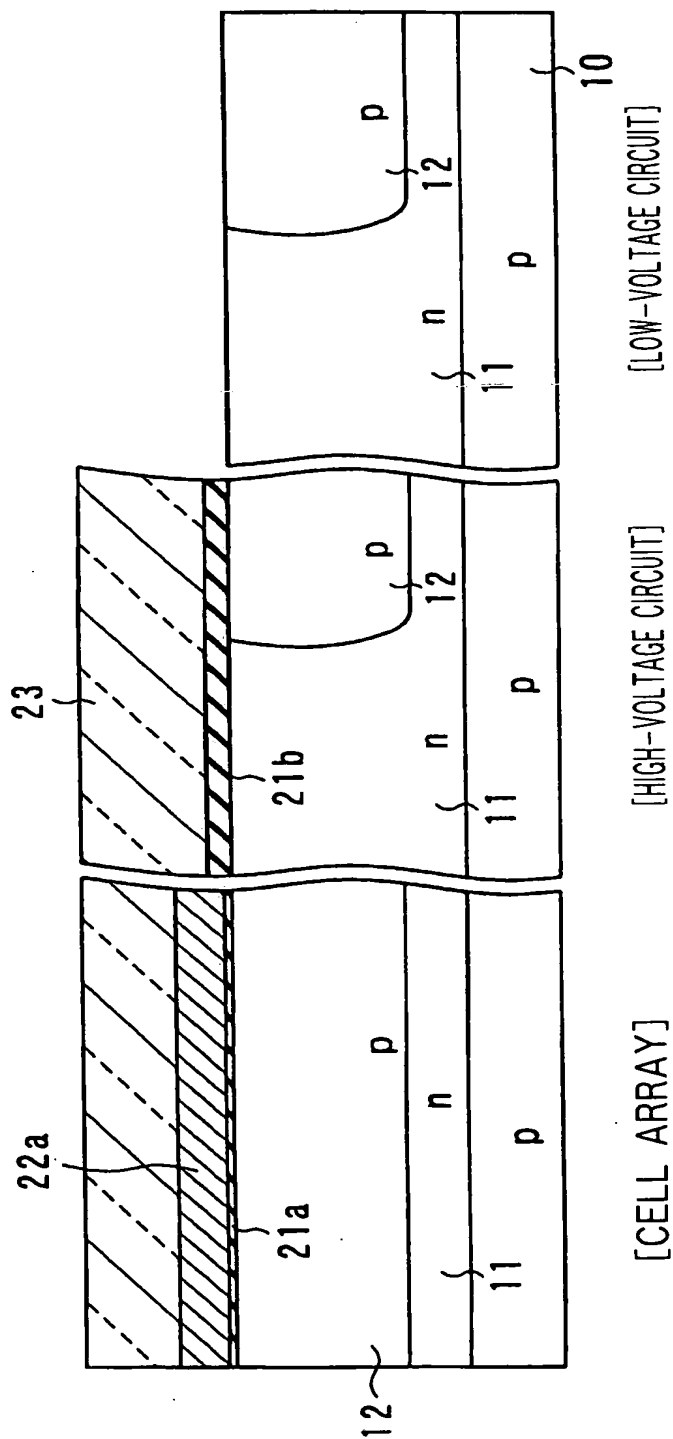


FIG. 3

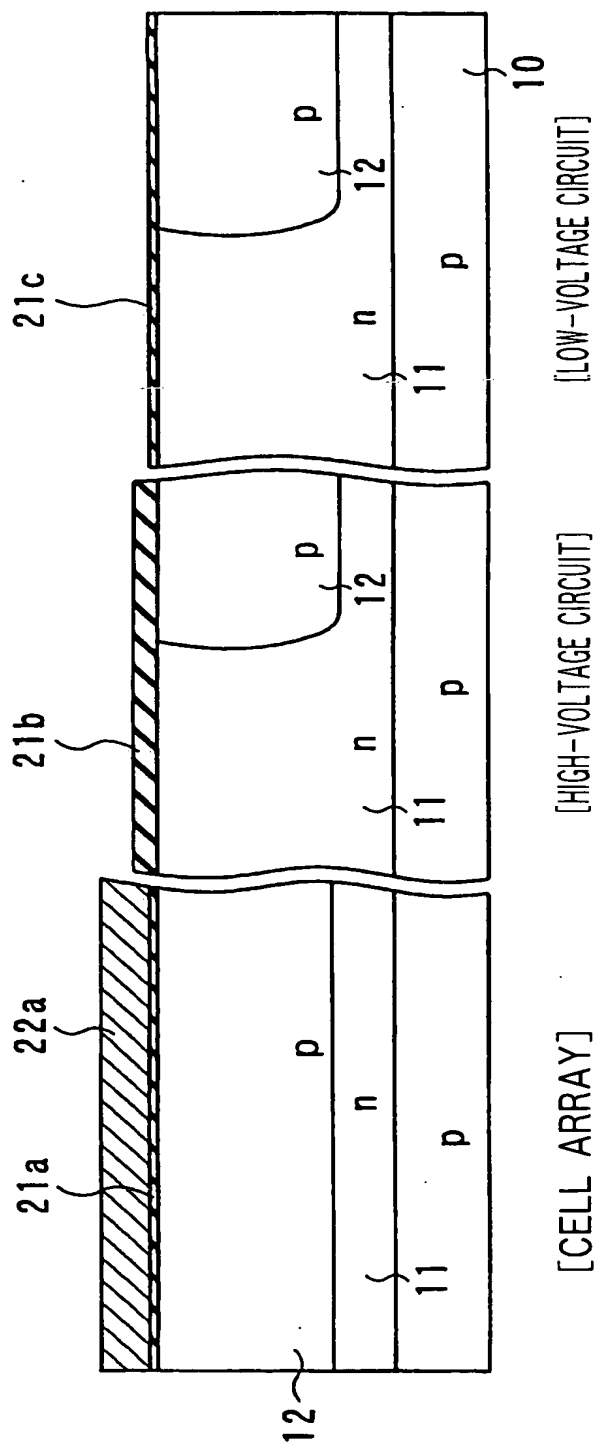


FIG. 4

FIG. 5

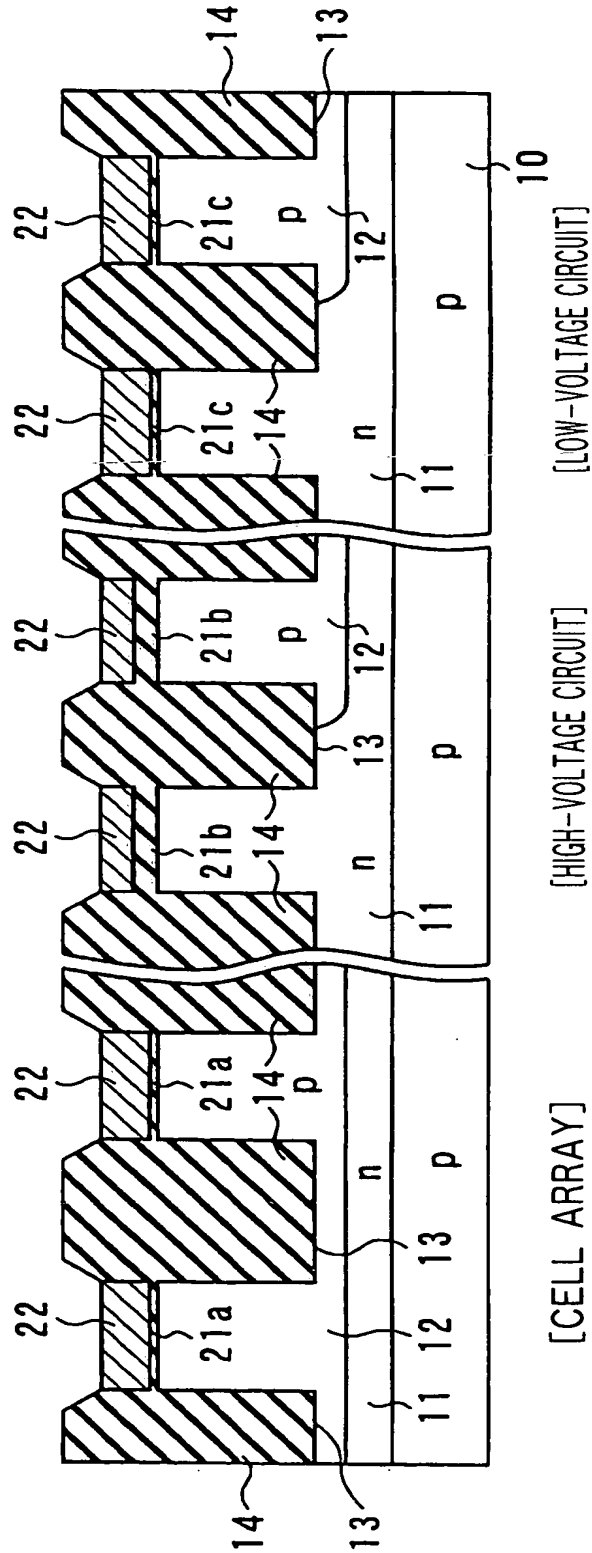


FIG. 6

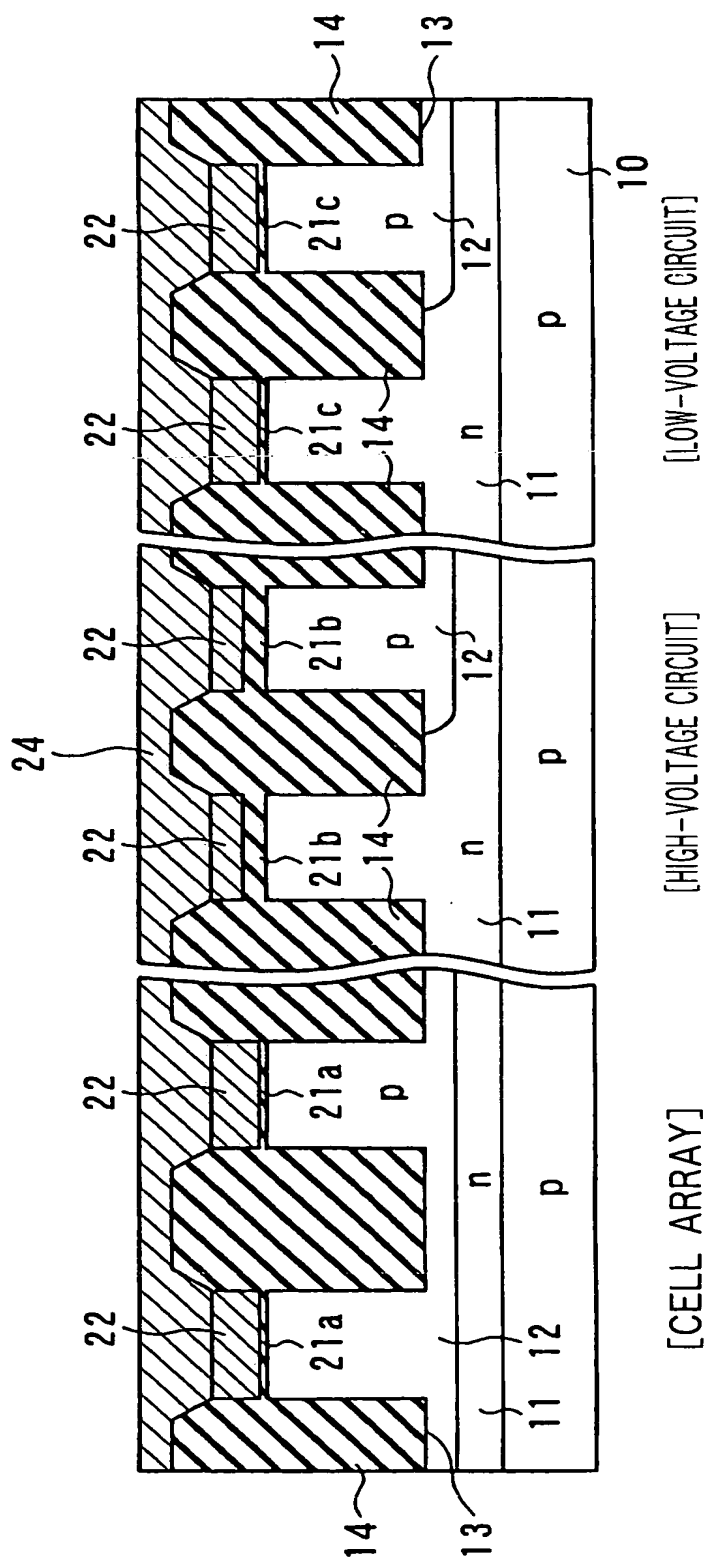
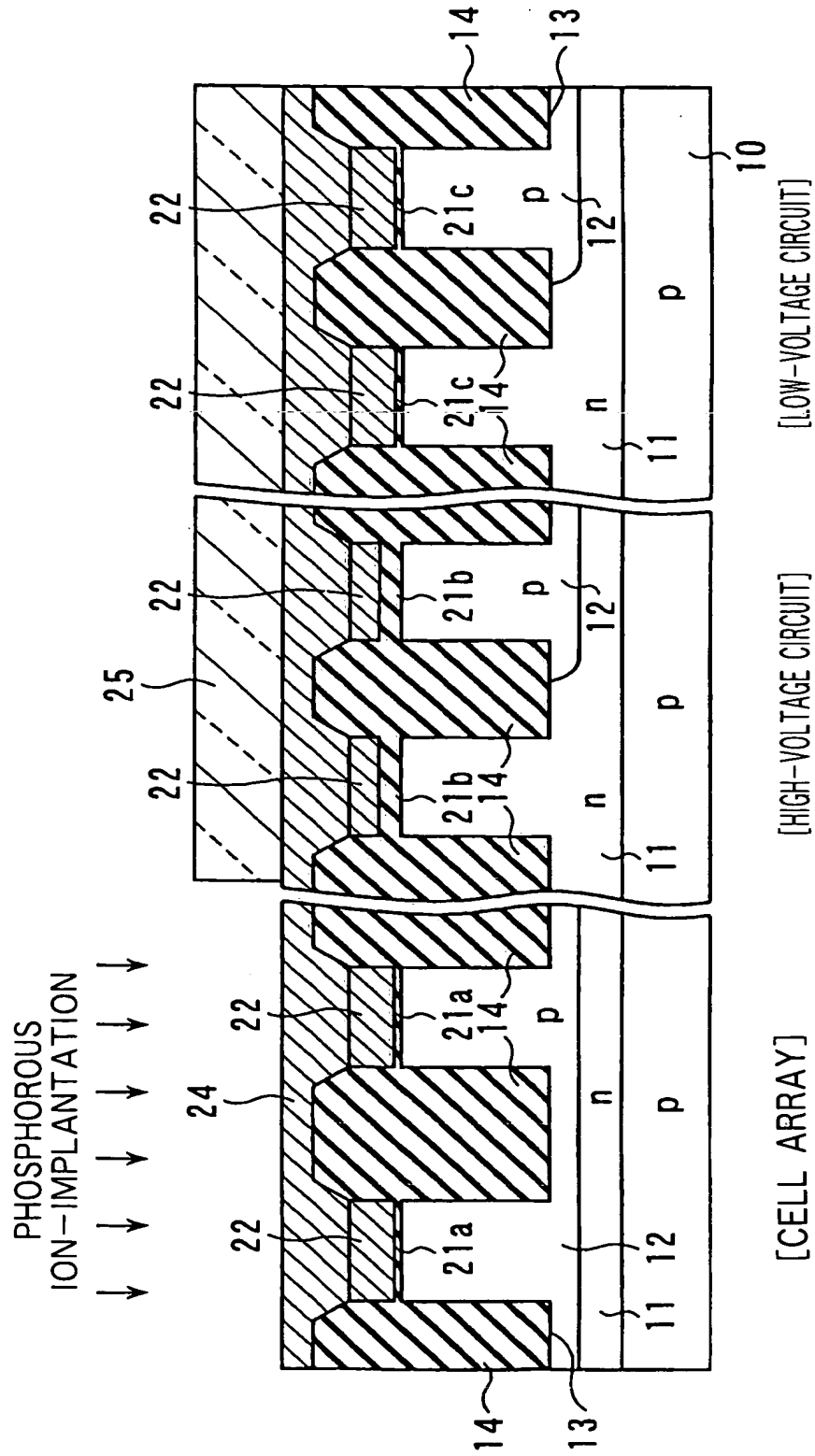


FIG. 7



FFG

9/41

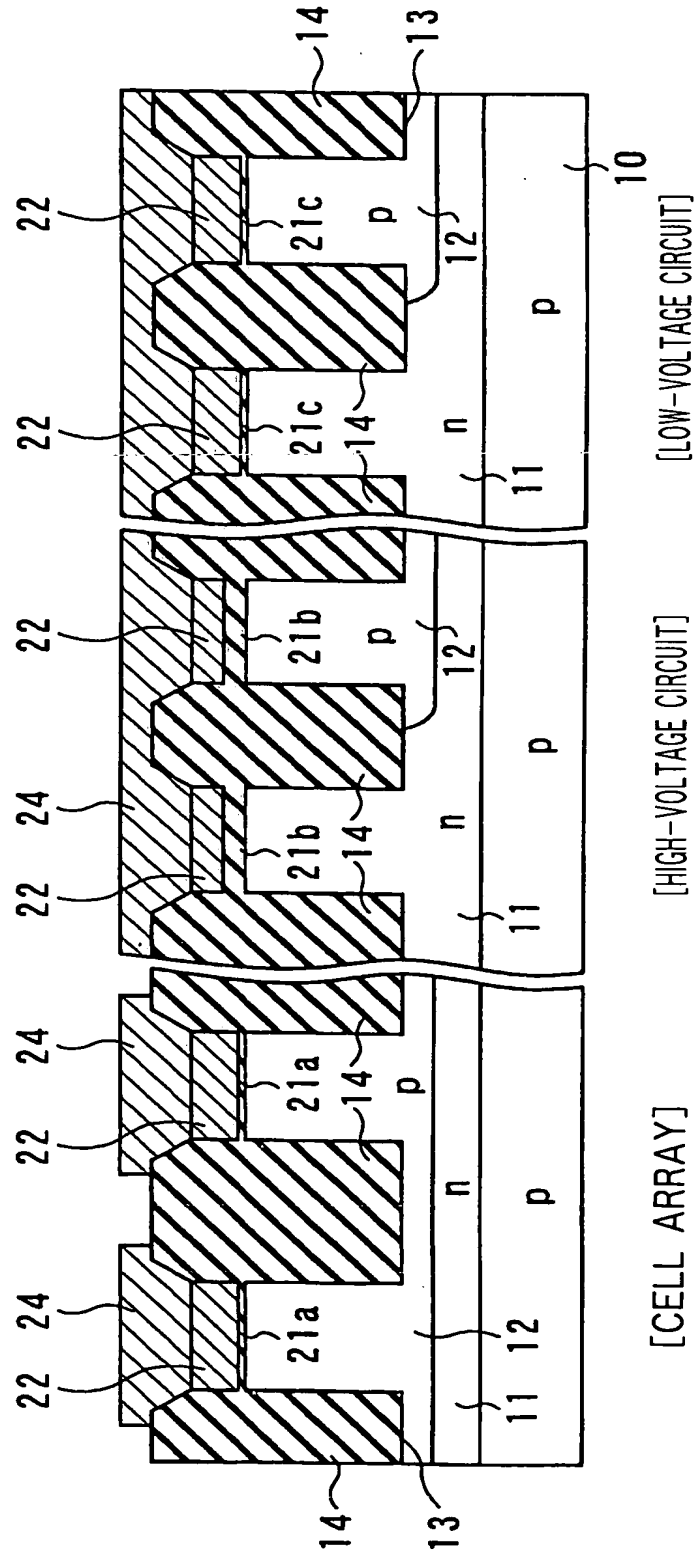


FIG. 9

FIG. 10

10/41

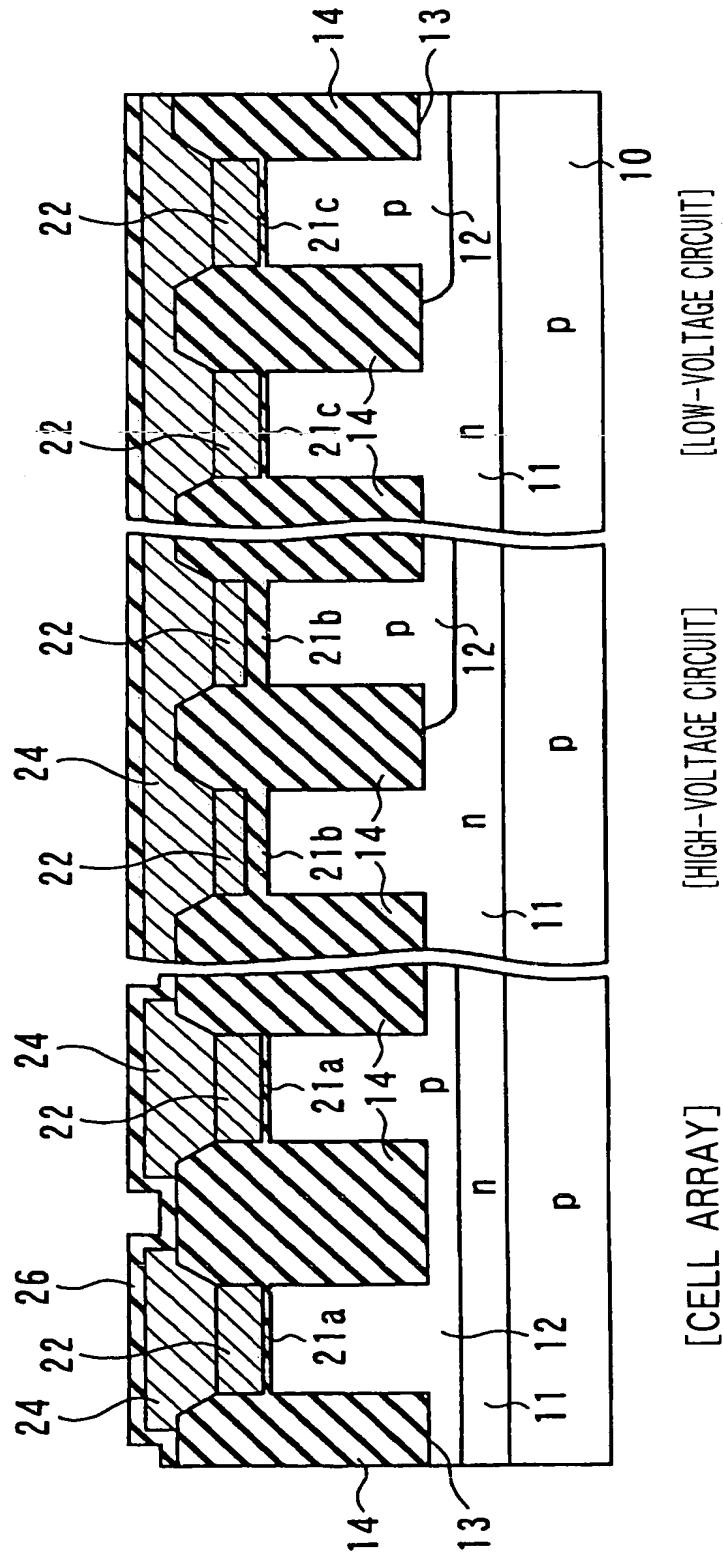


FIG. 10

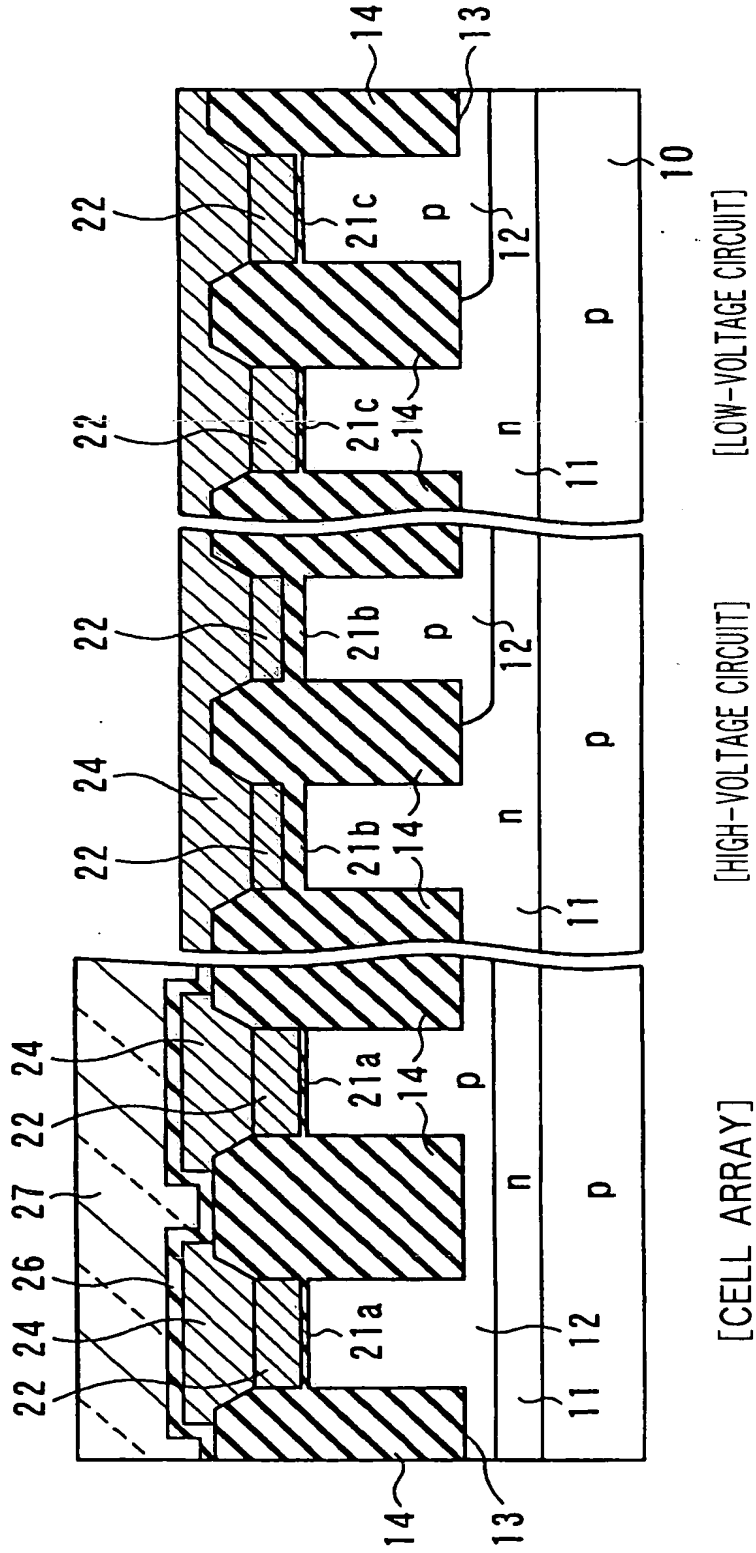


FIG. 11

FIG. 12

13/41

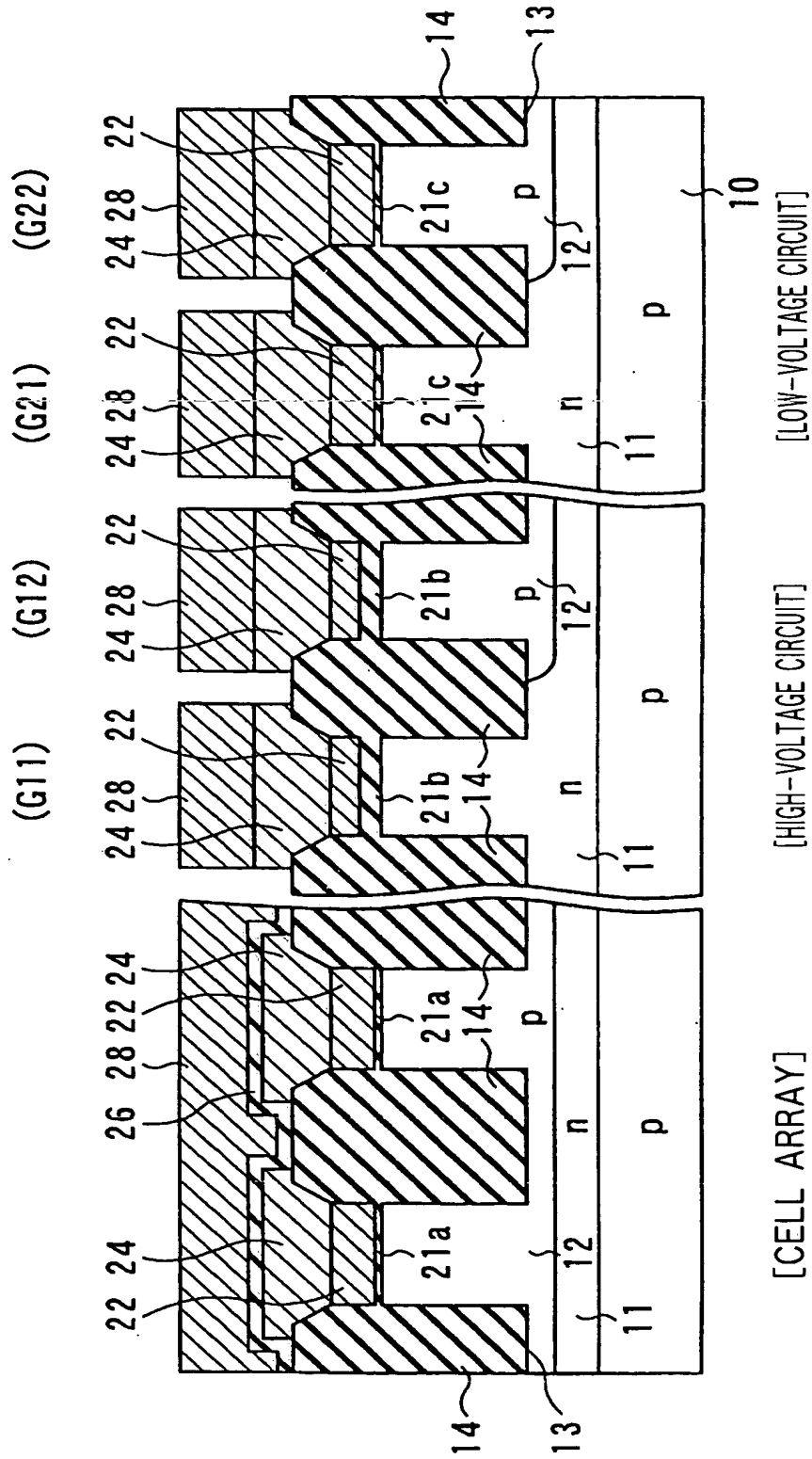


FIG. 13

14/41

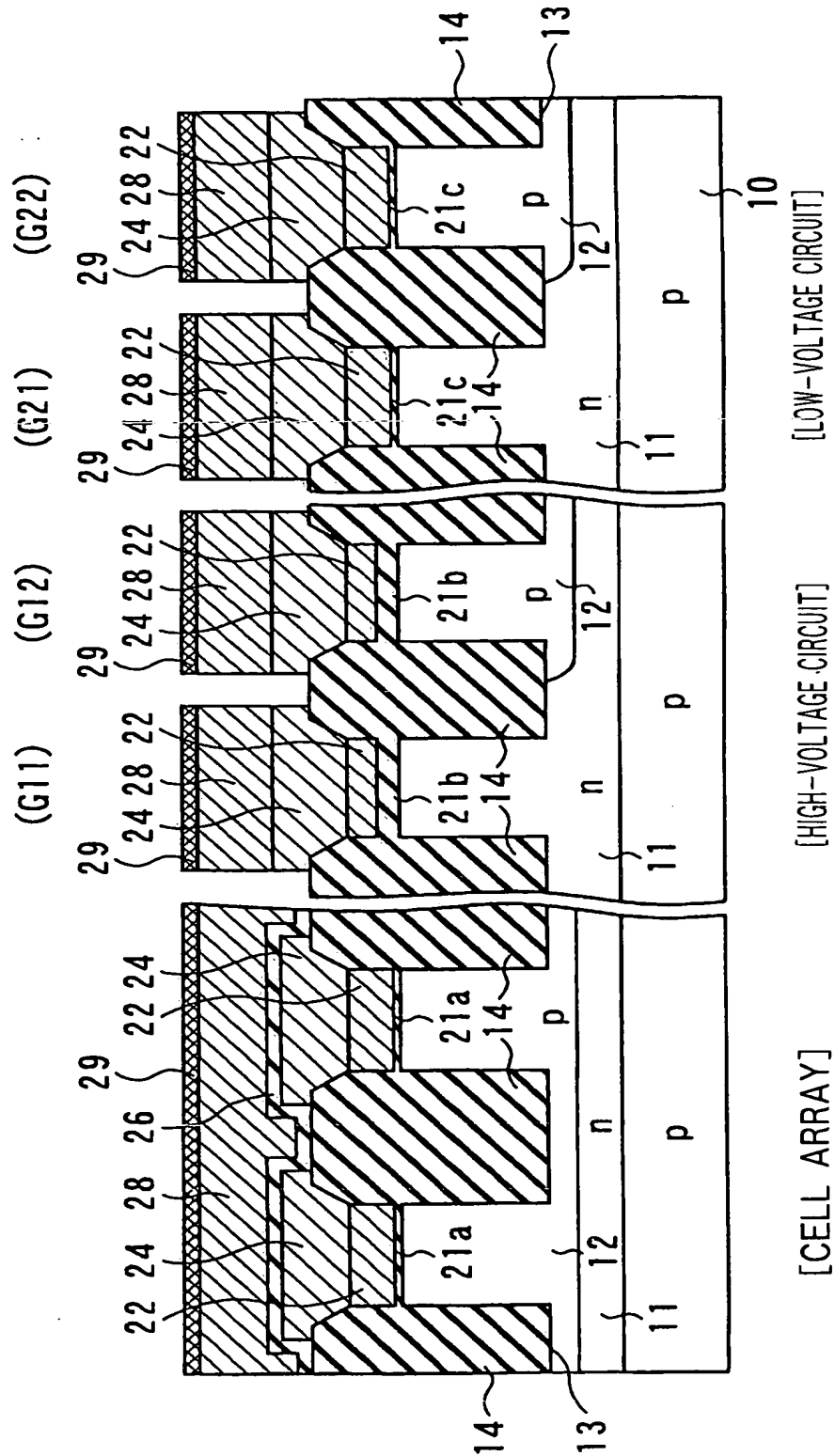


FIG. 14

15/41

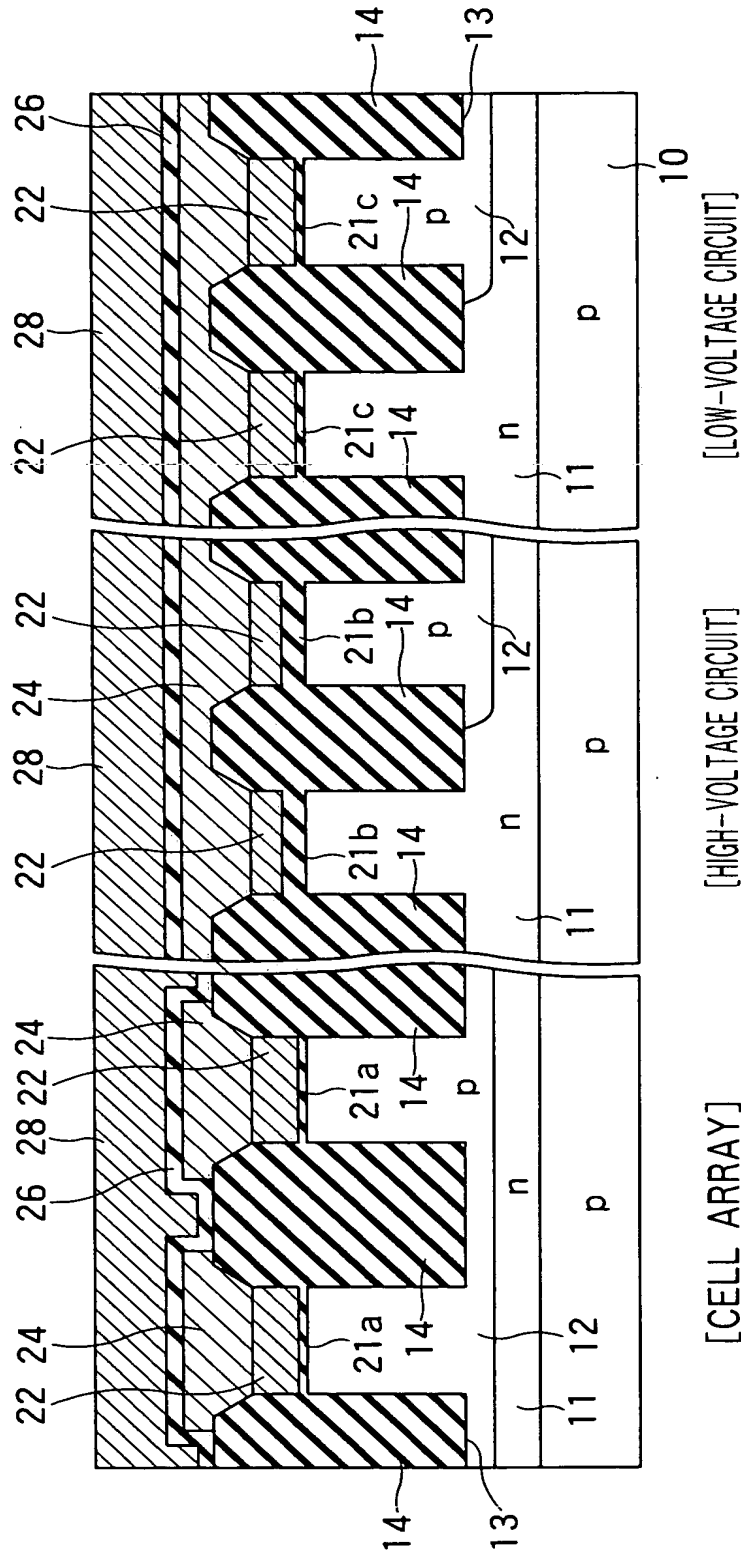


FIG. 14A

16/41

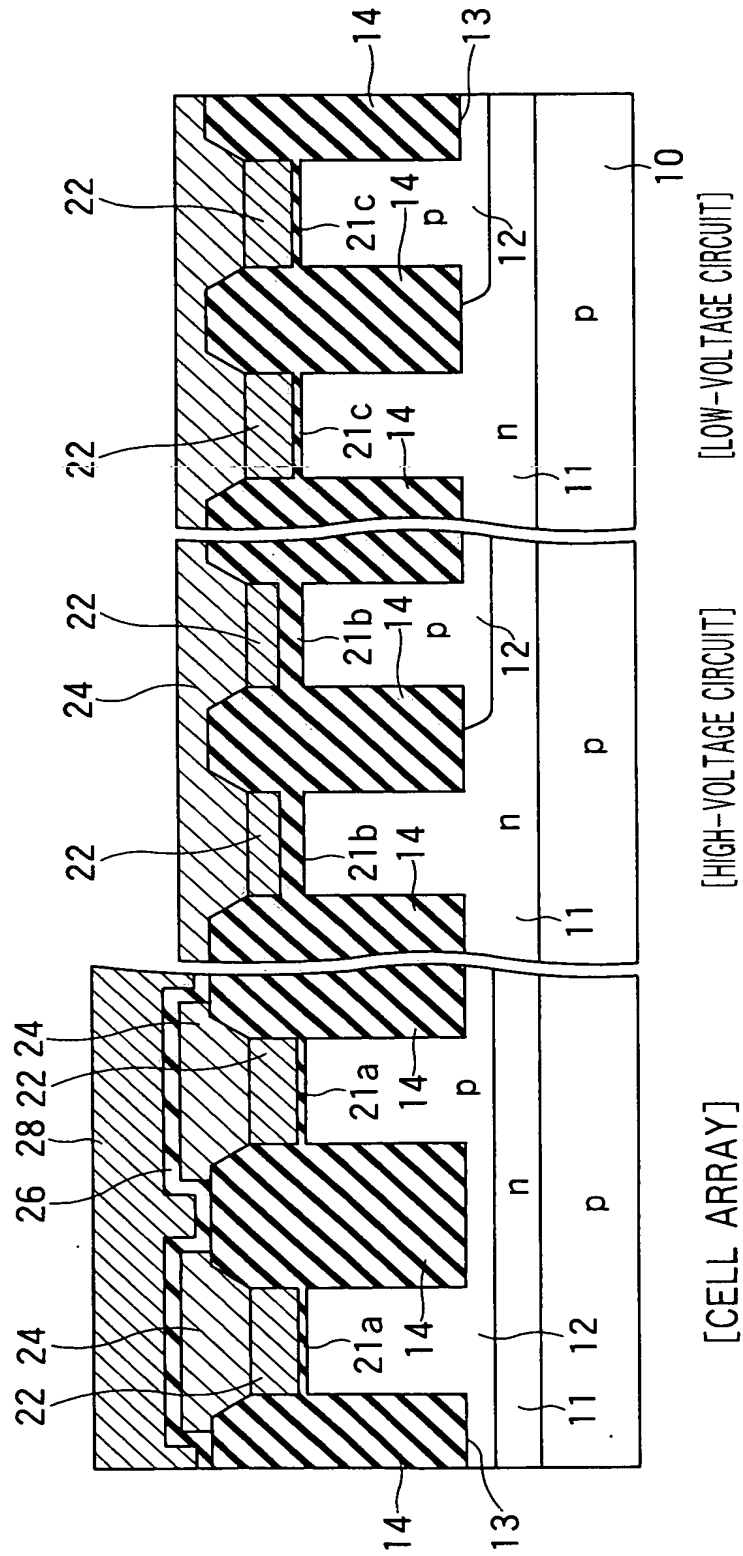


FIG. 14B

17/41

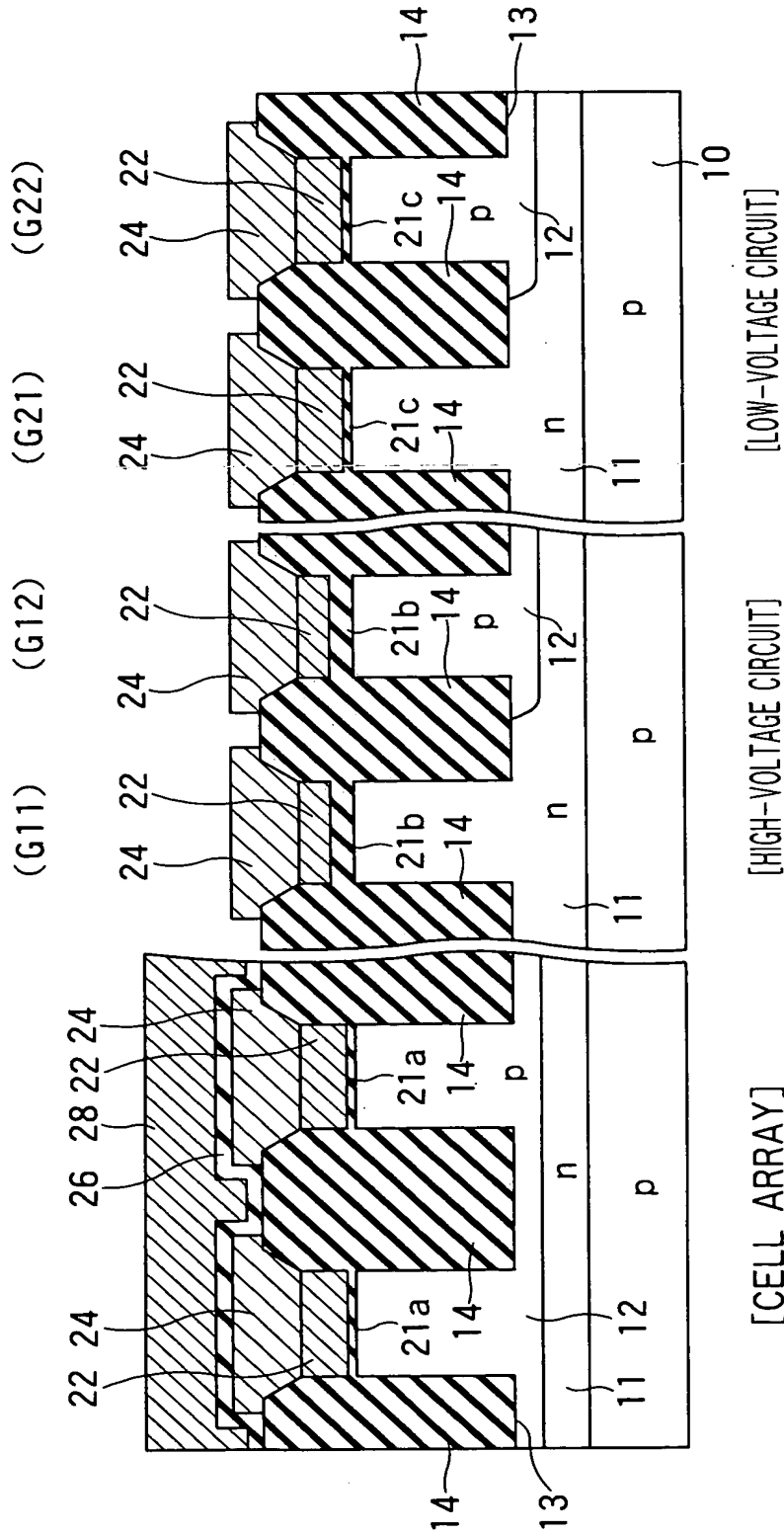


FIG. 14C

18/41

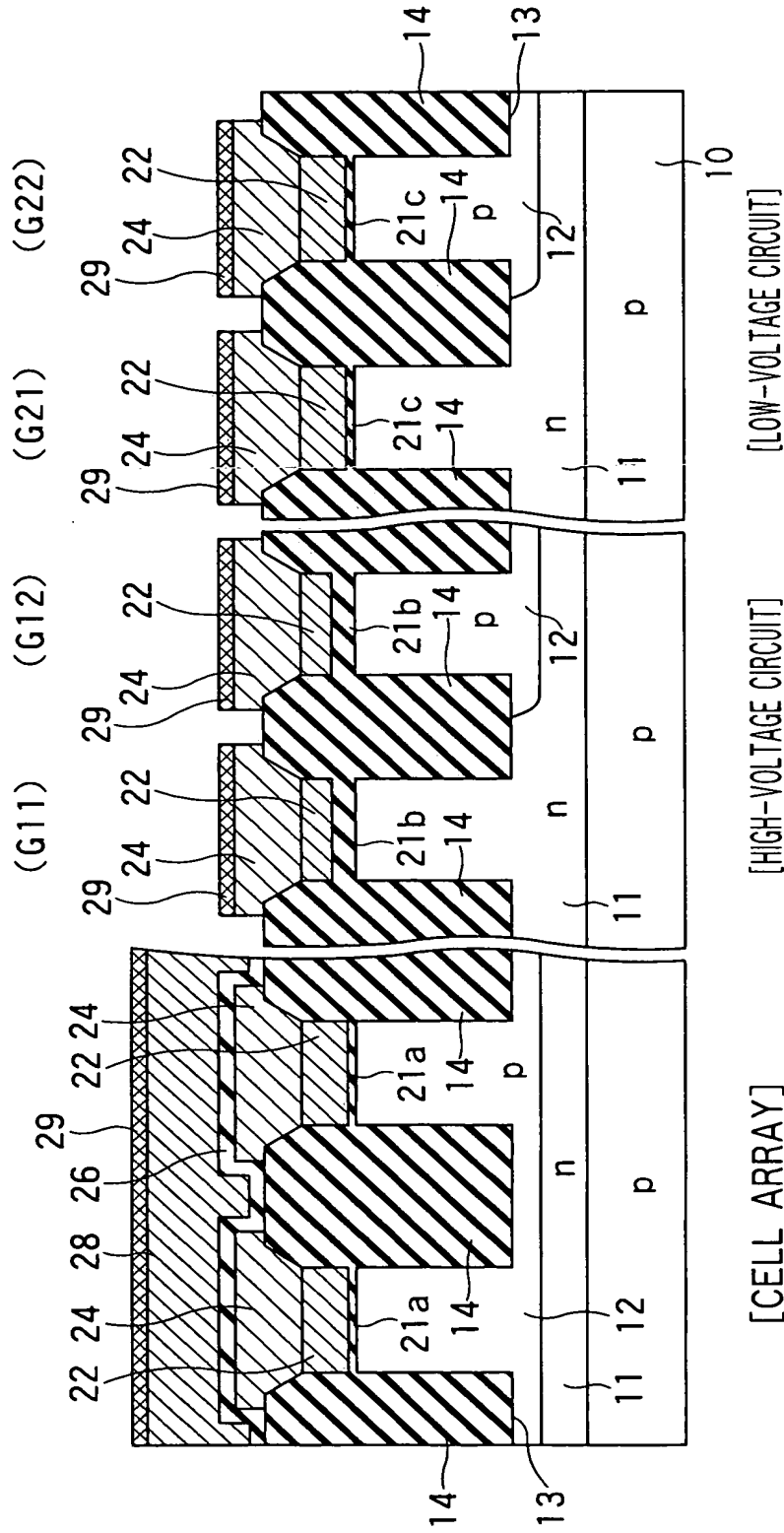
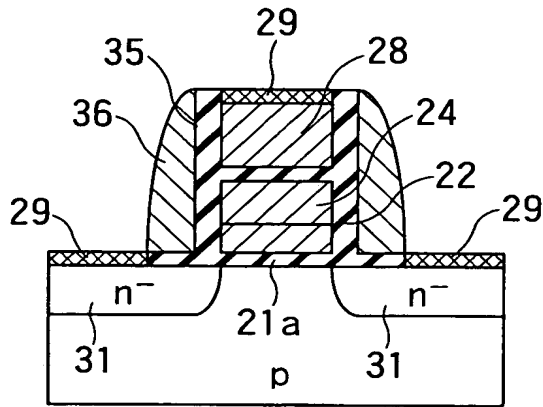
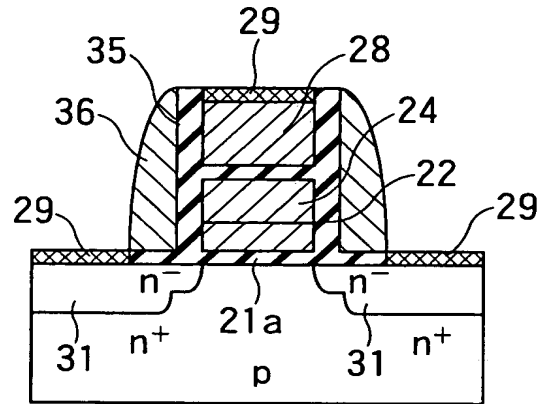


FIG. 14D

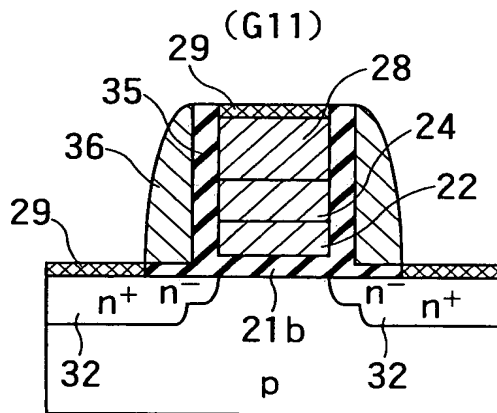
19/41



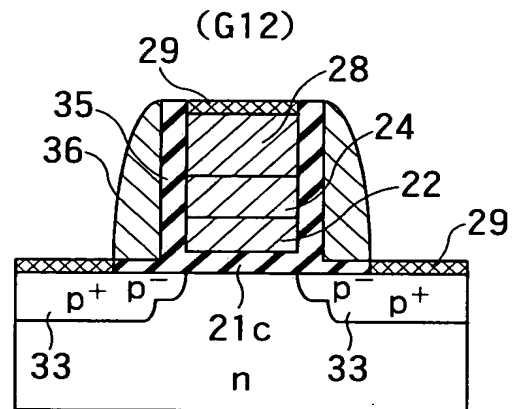
[MEMORY CELL]



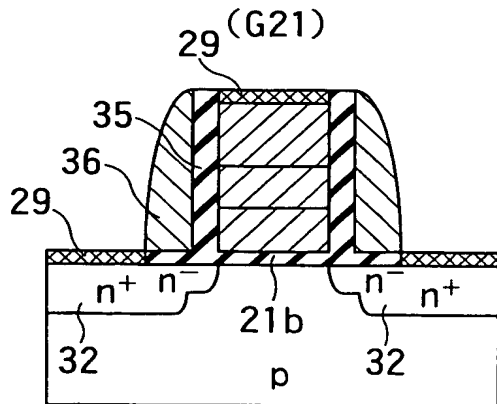
[MEMORY CELL]



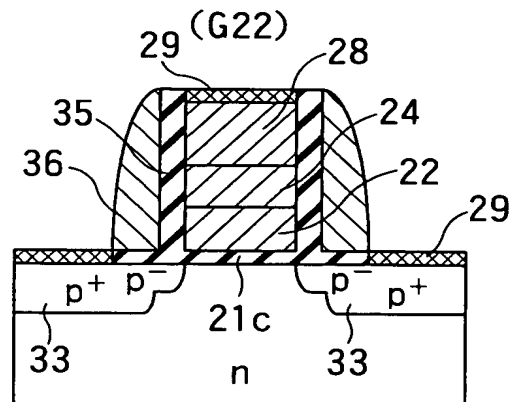
[HIGH-VOLTAGE NMOS]



[HIGH-VOLTAGE PMOS]



[LOW-VOLTAGE NMOS]



[LOW-VOLTAGE PMOS]

FIG. 15

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20/41

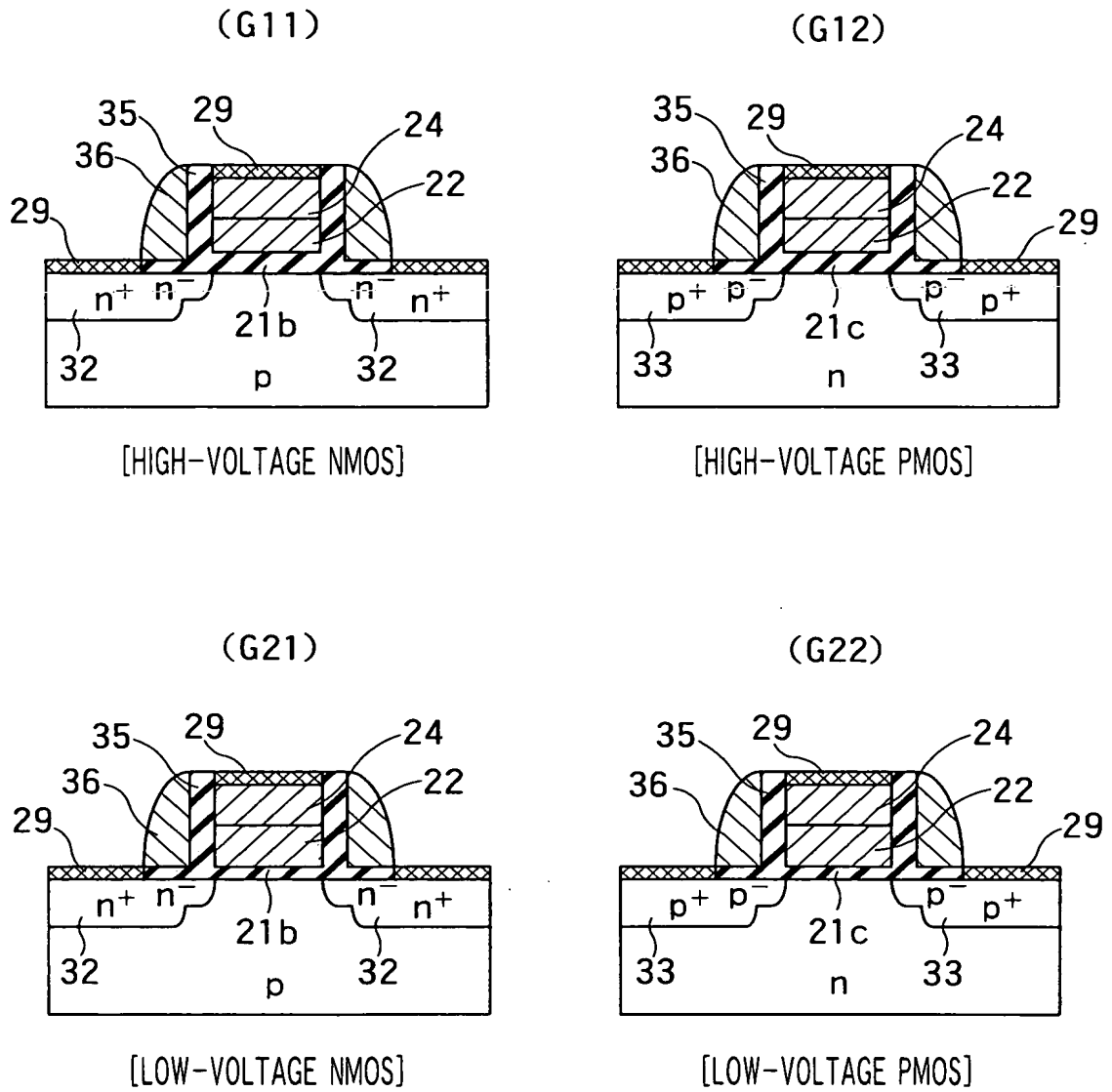


FIG. 15A

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FIG. 16

22/41

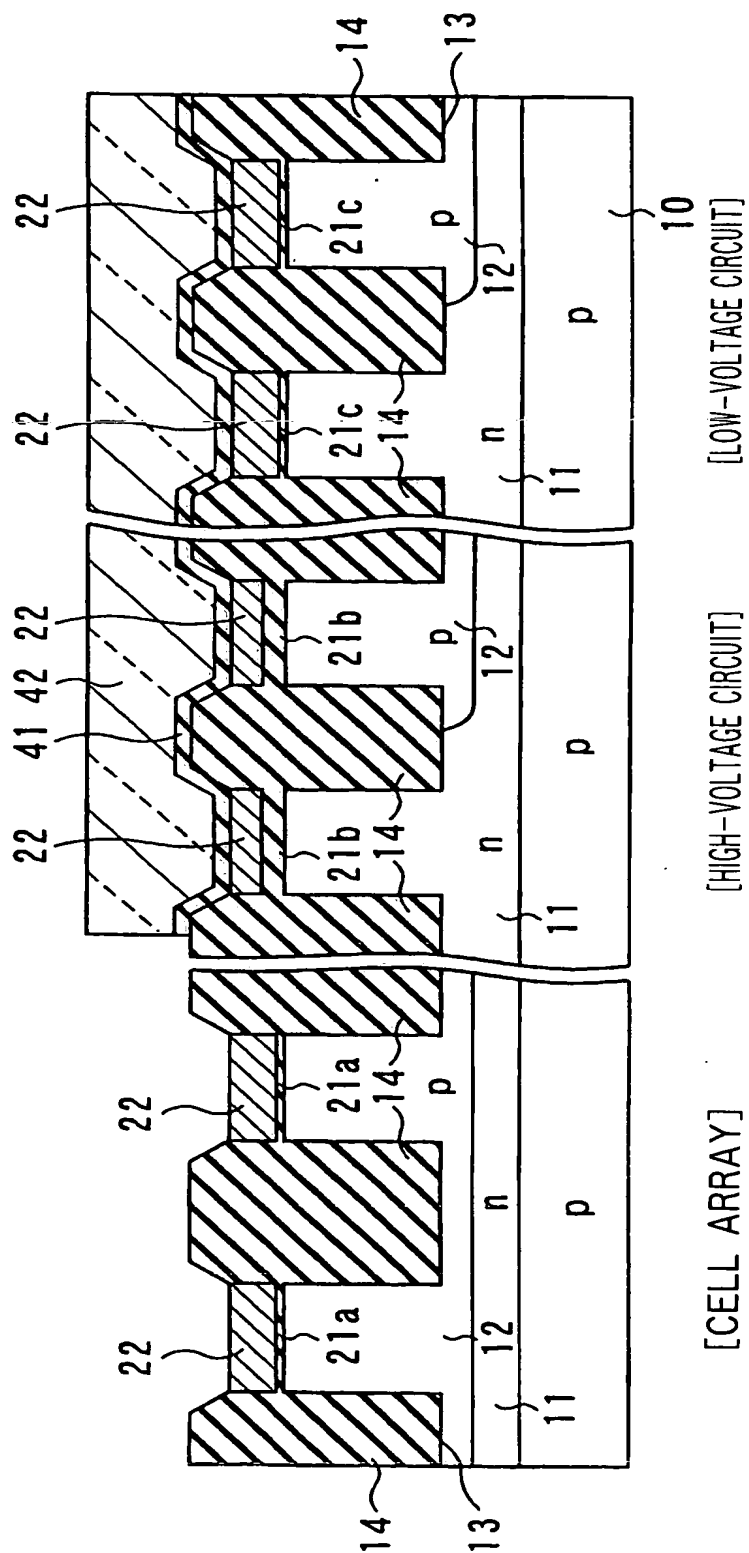


FIG. 17

23/41

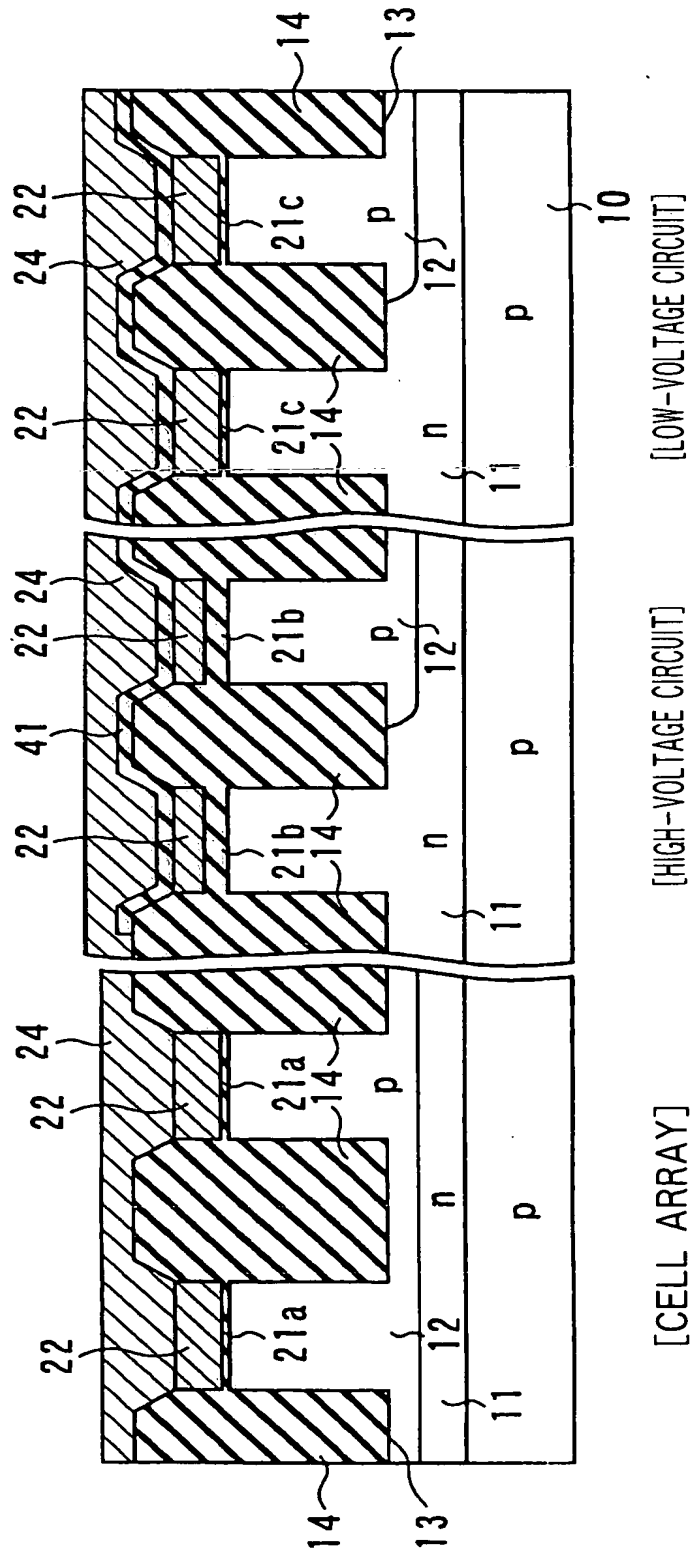


FIG. 18

24/41

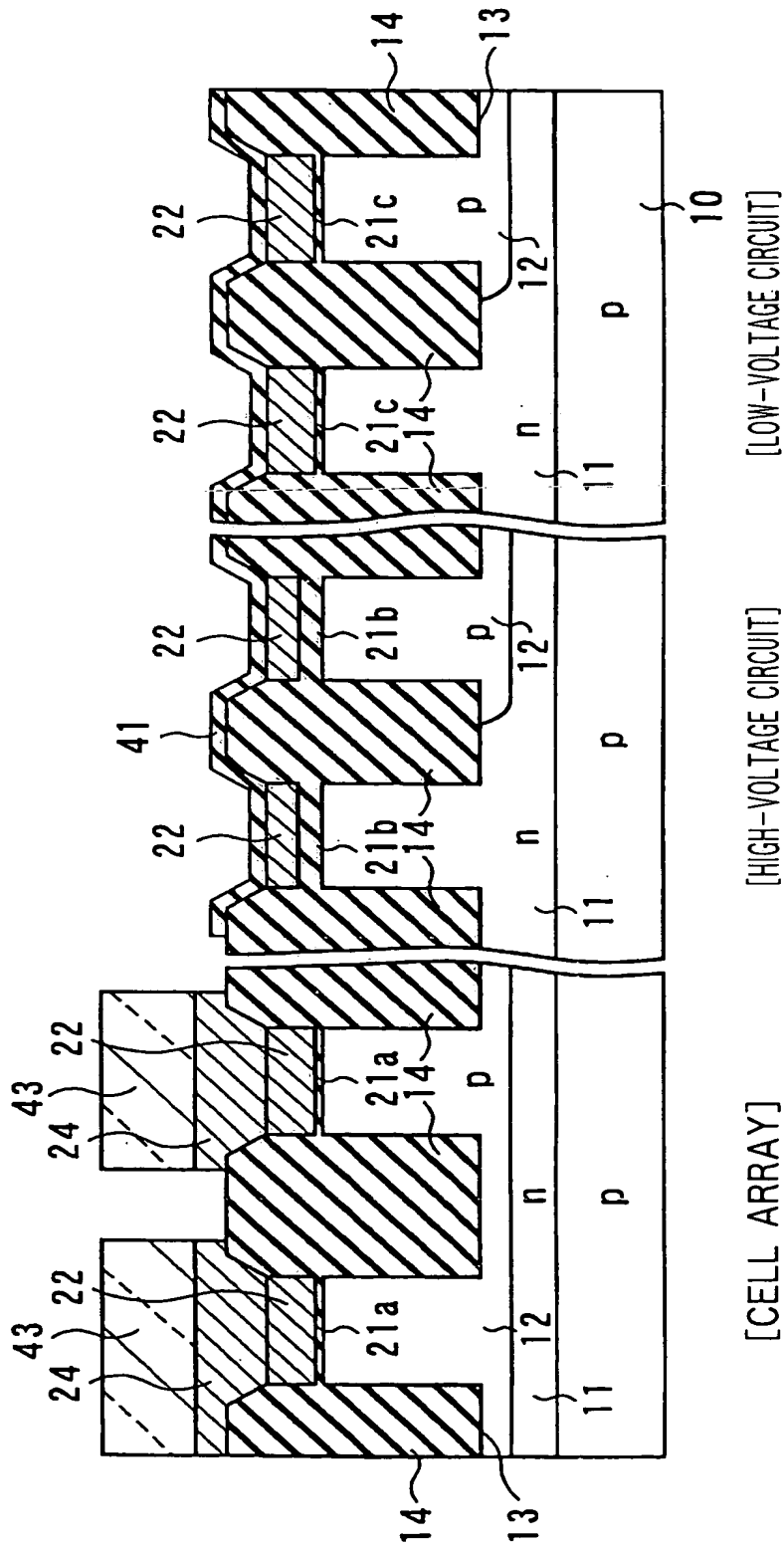


FIG. 19

25/41

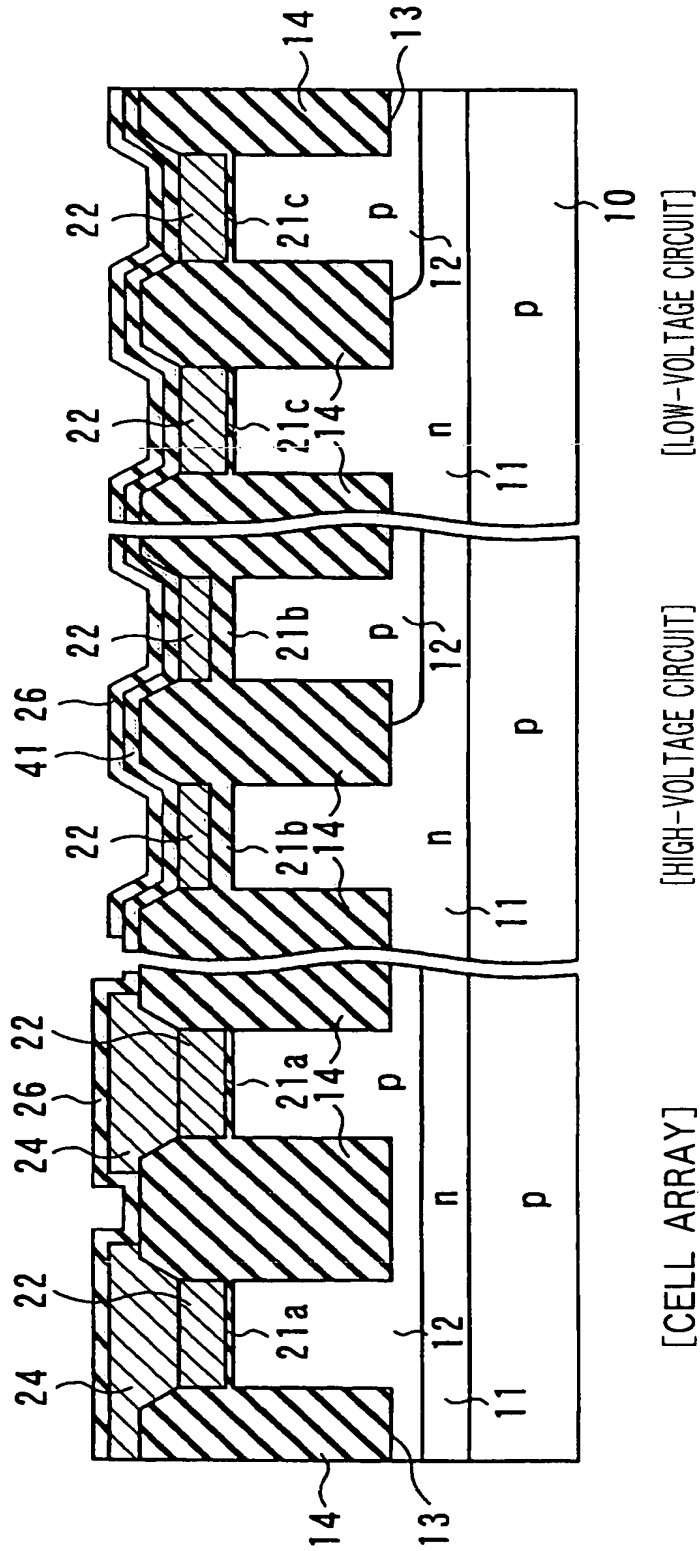


FIG. 20

26/41

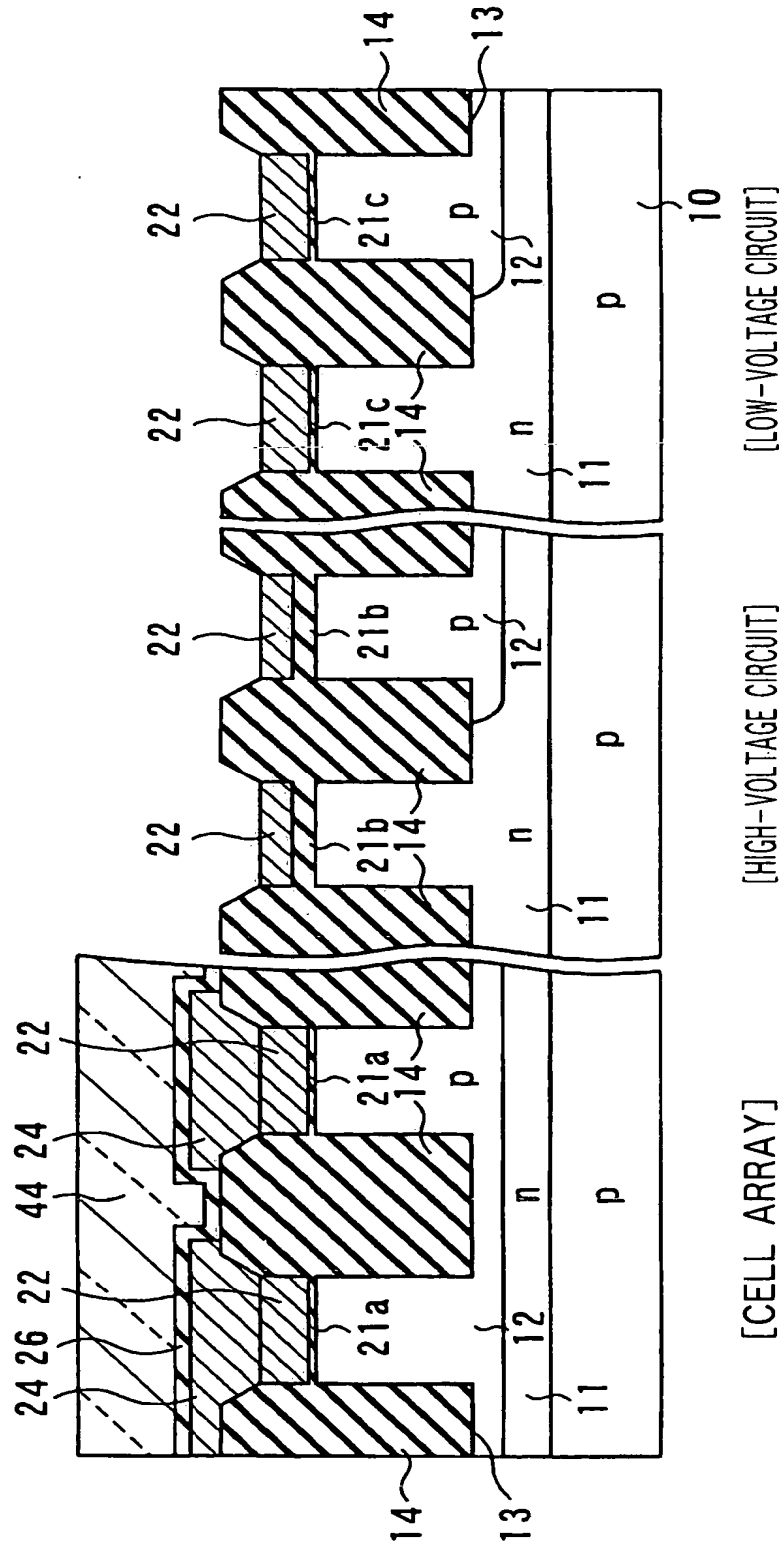


FIG. 21

27/41

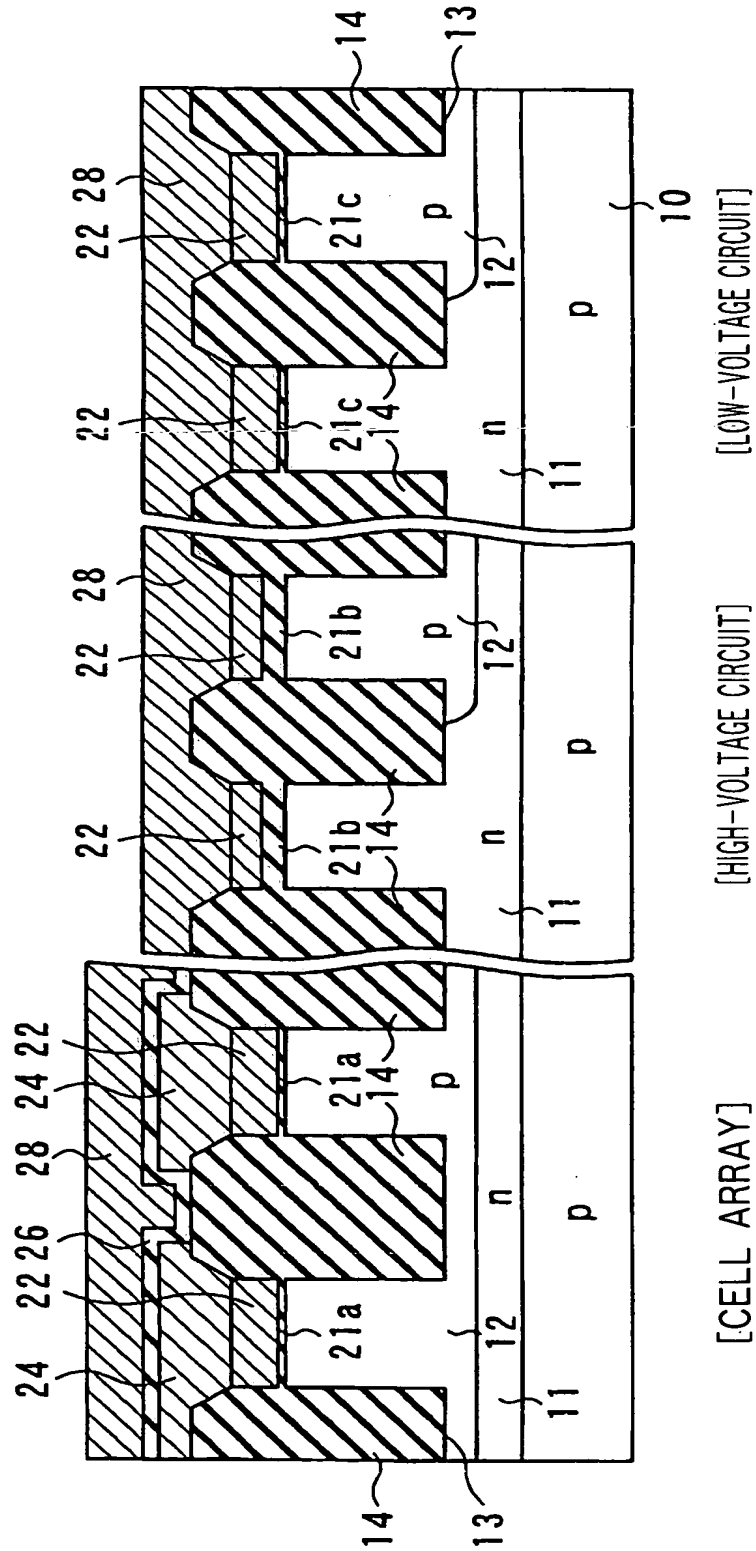


FIG. 22

28/41

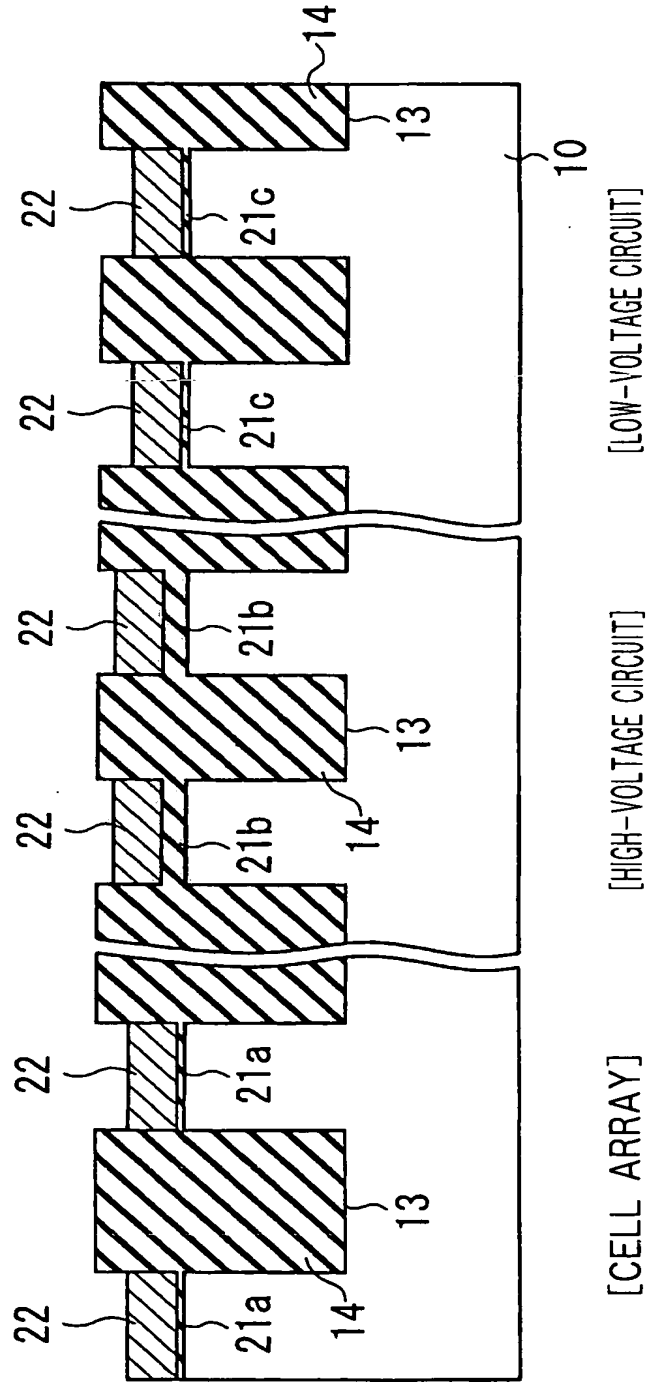


FIG. 23

29/41

PHOSPHOROUS
ION-IMPLANTATION

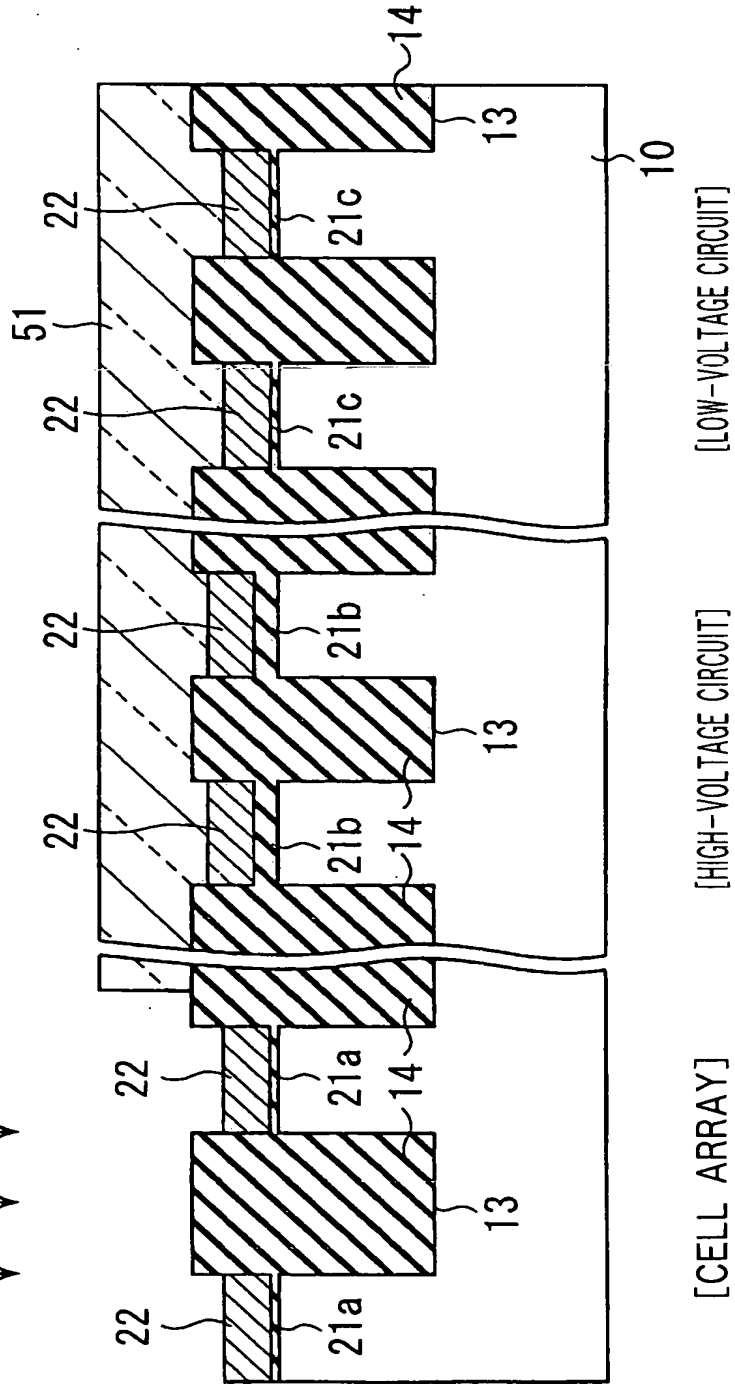


FIG. 24

30/41

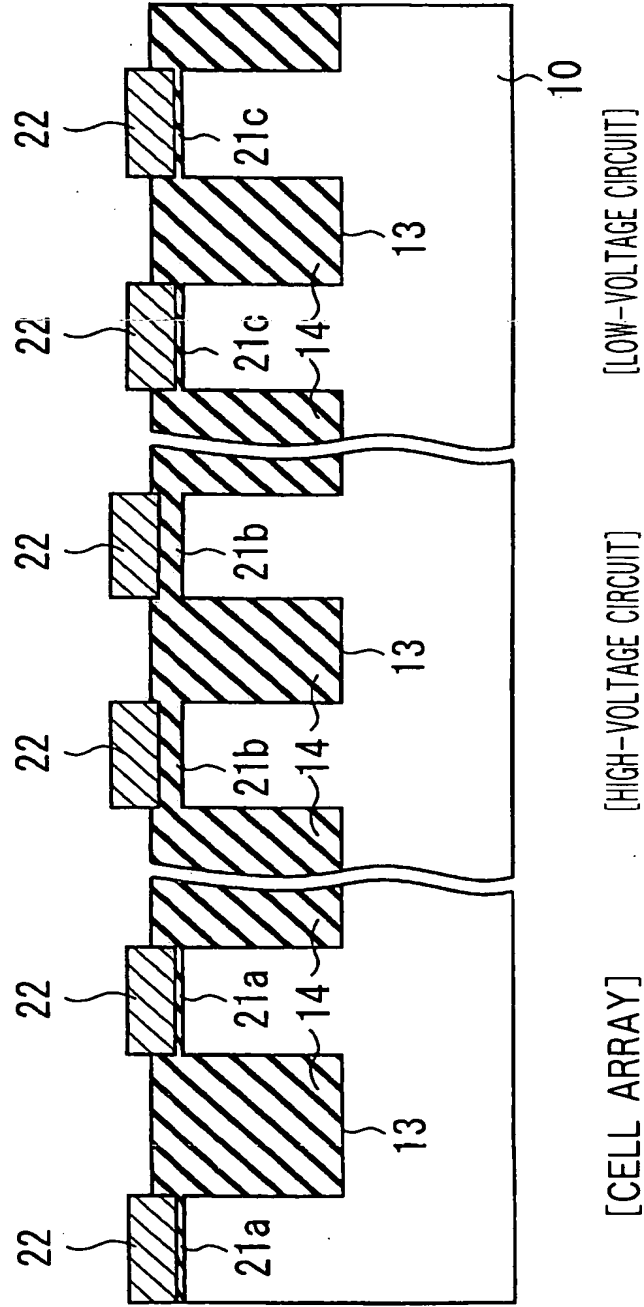


FIG. 25

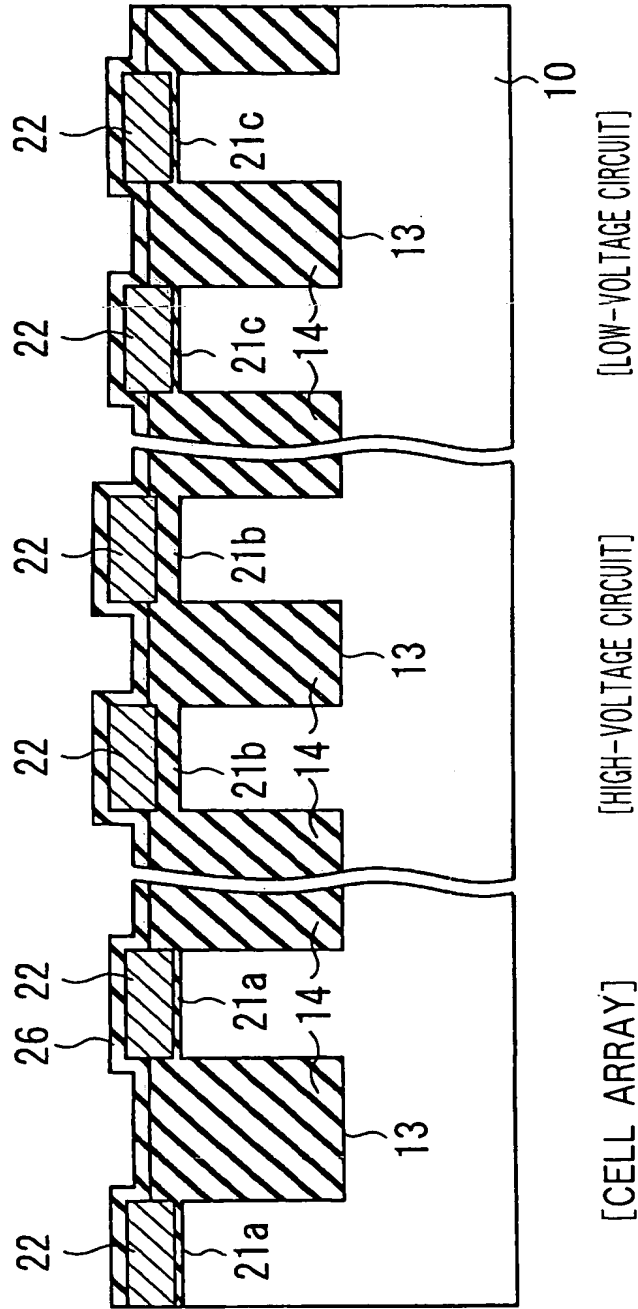


FIG. 26

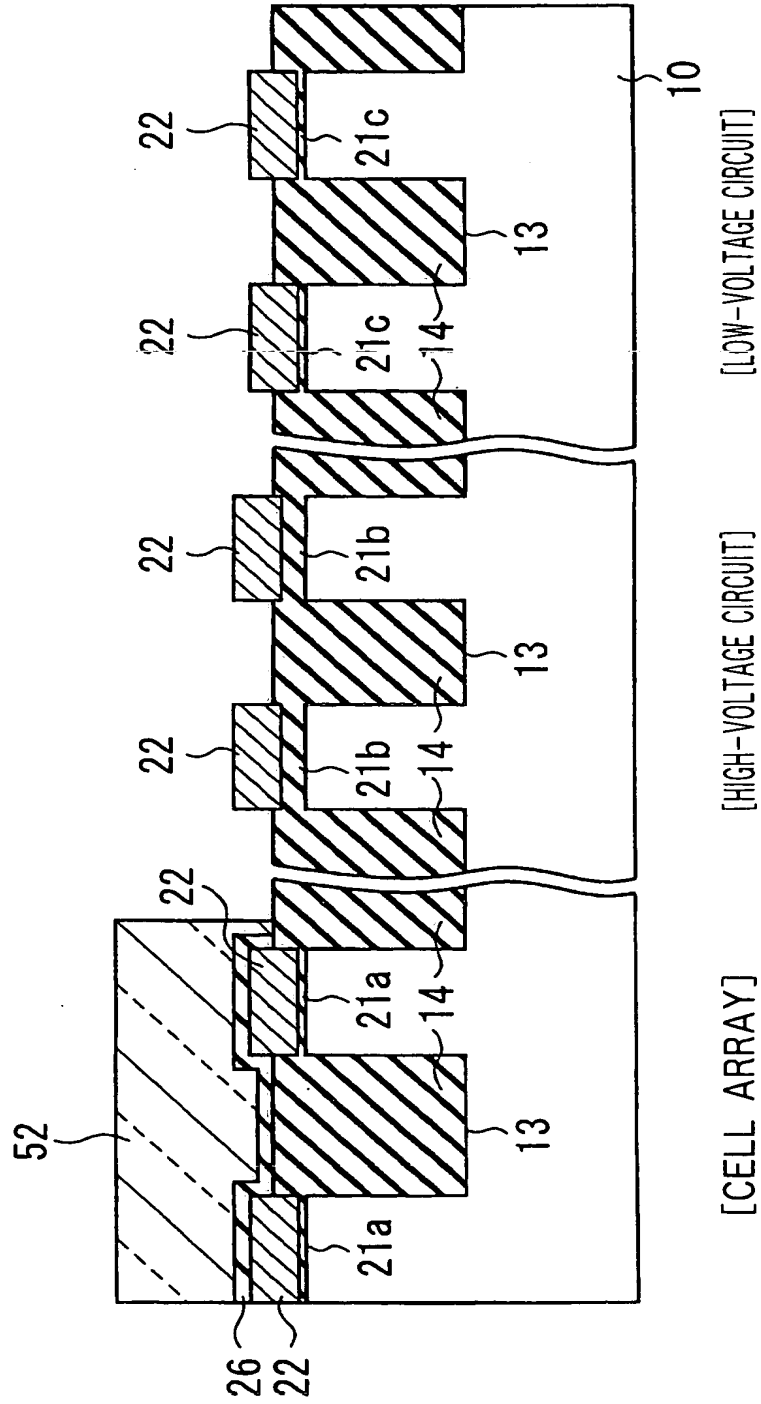


FIG. 27

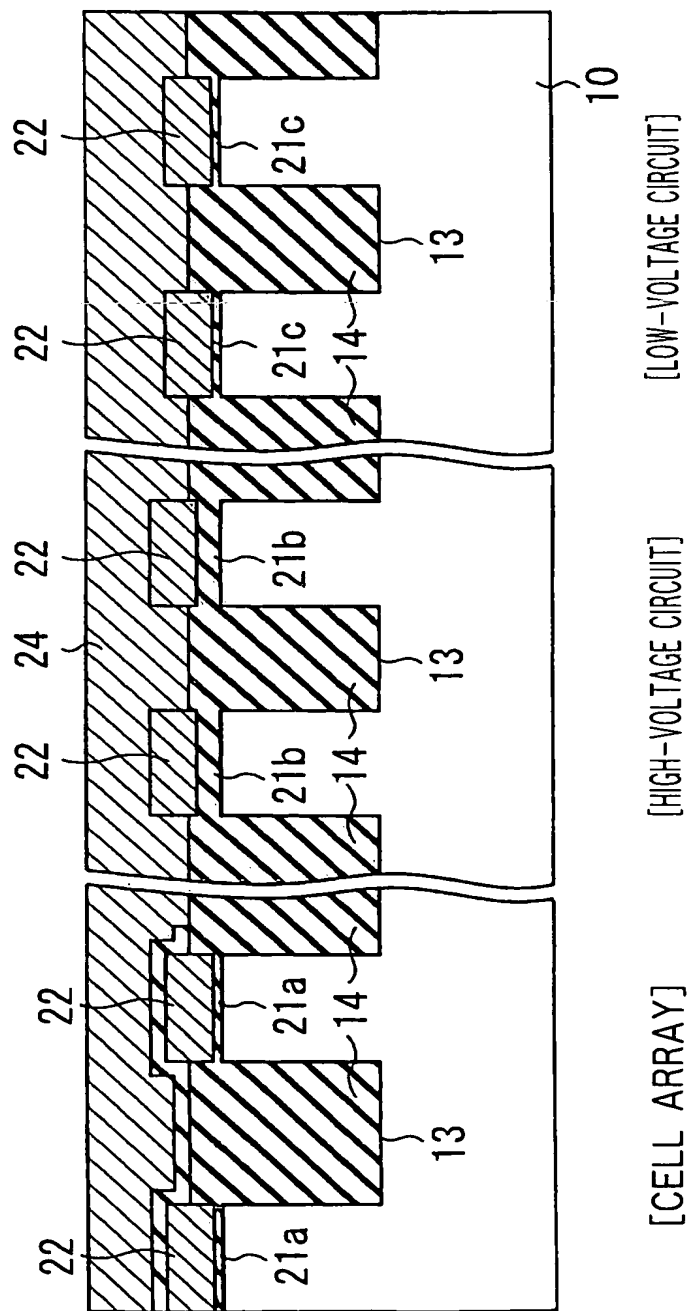


FIG. 28

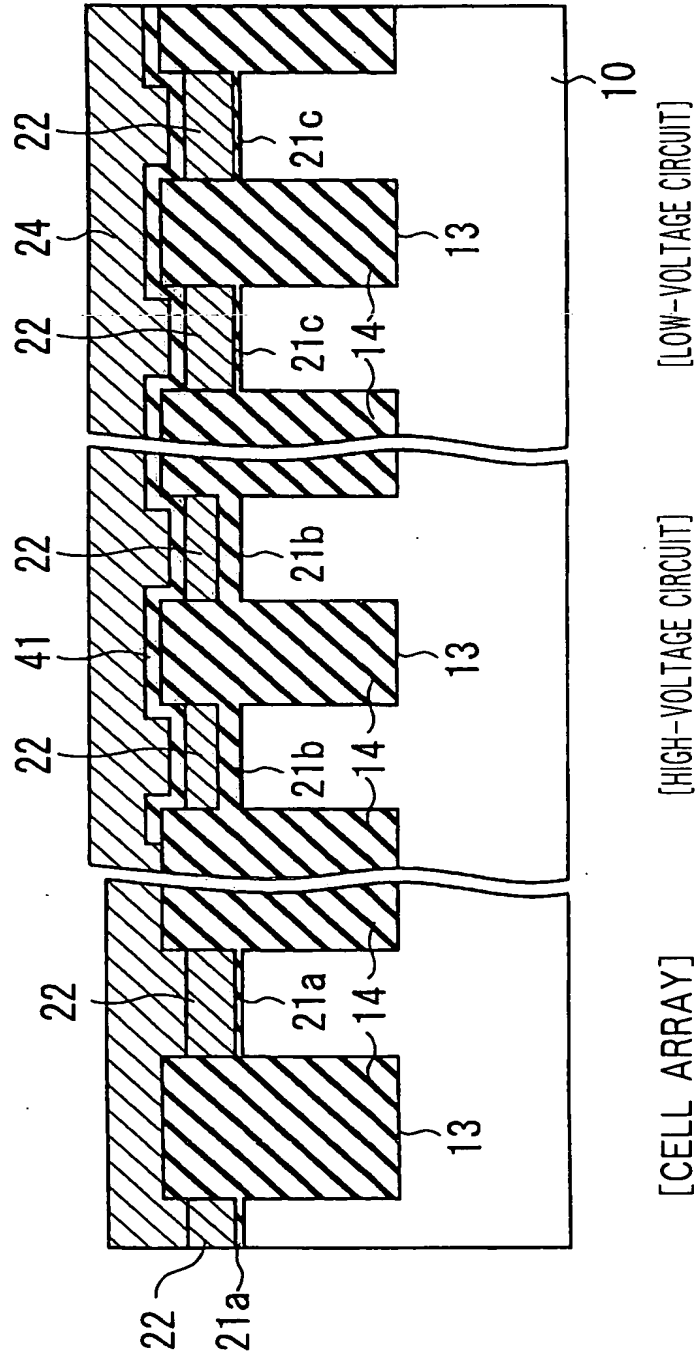


FIG. 29

35/41

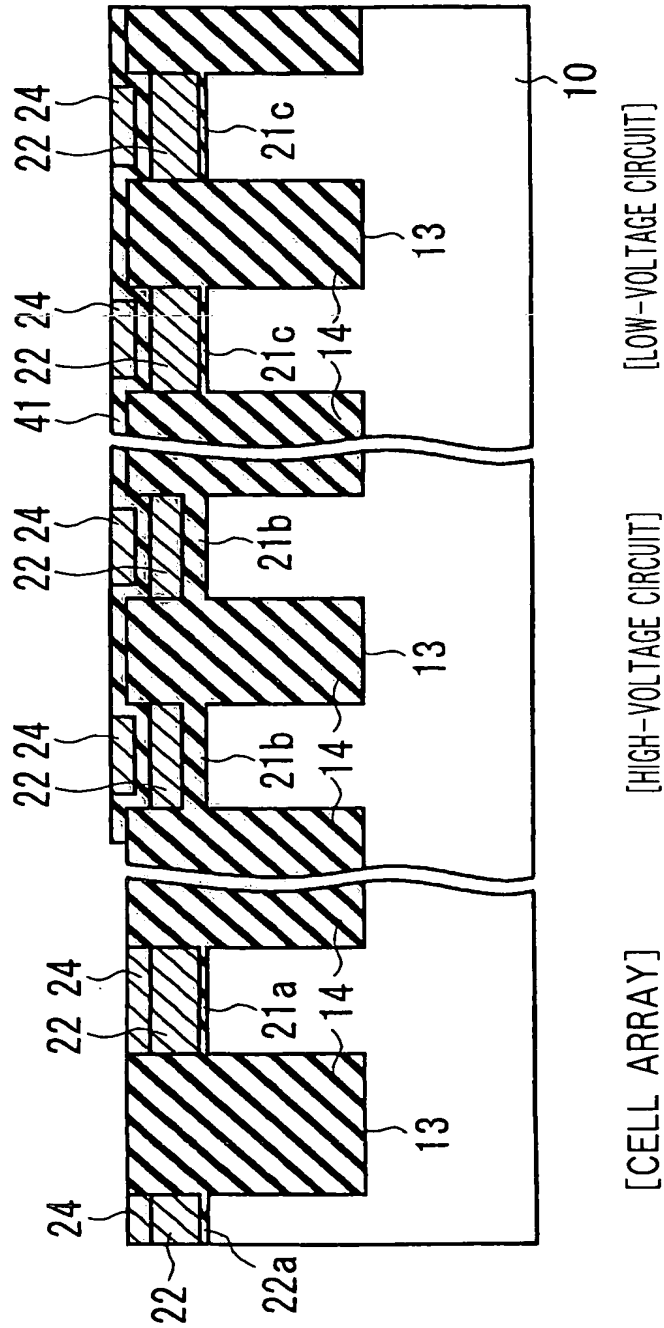


FIG. 30

FIG. 31

36/14

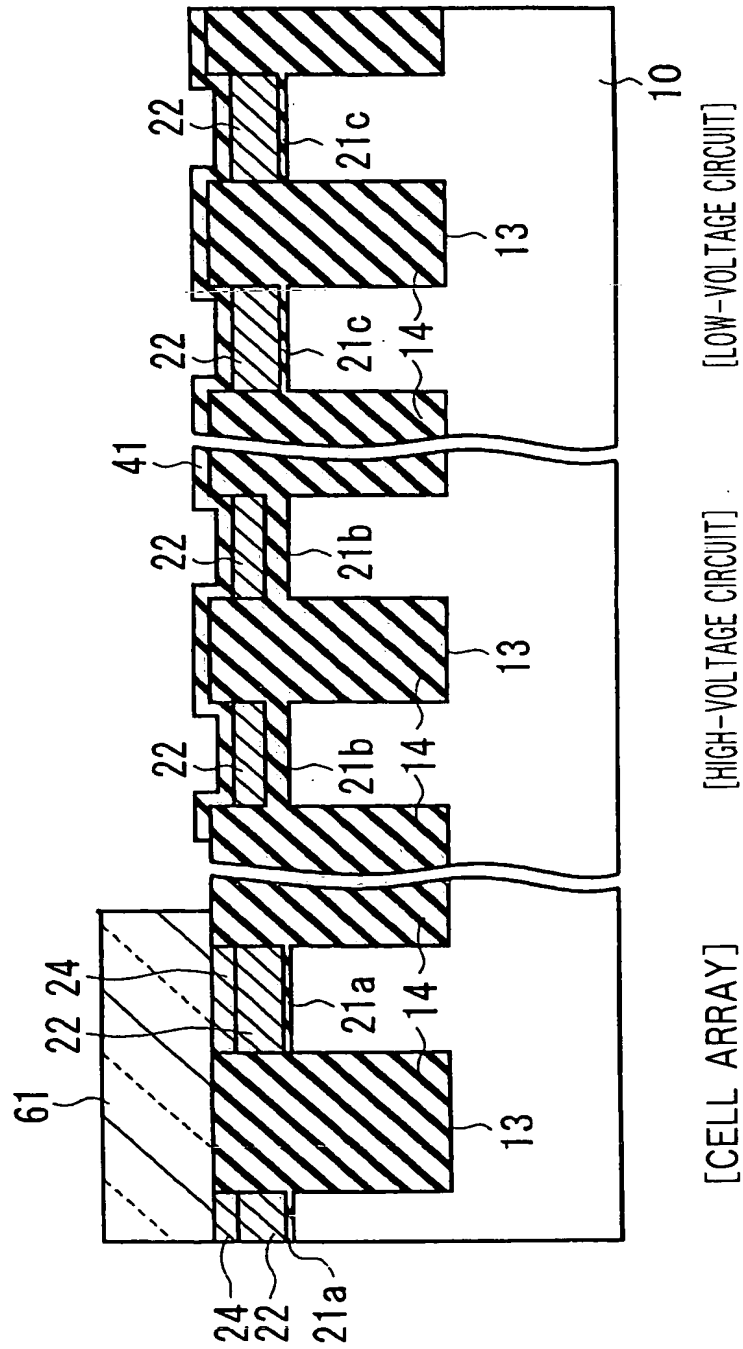


FIG. 31

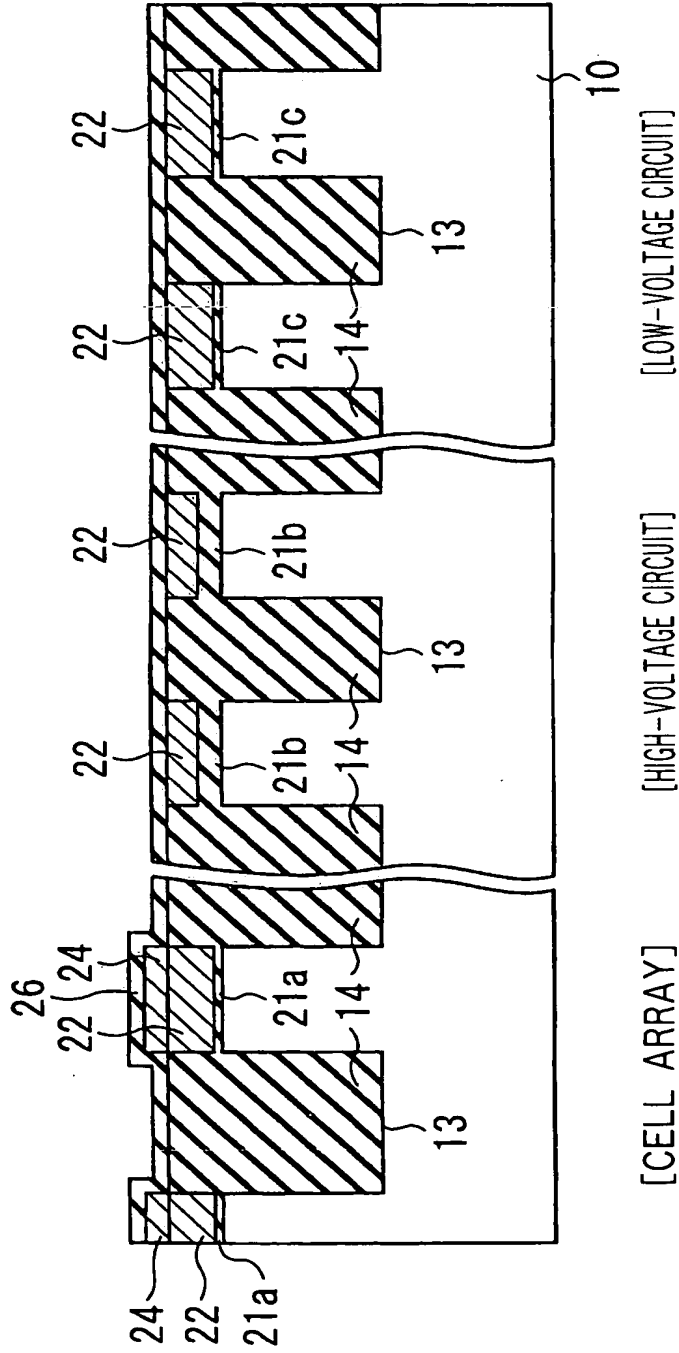


FIG. 32

38/41

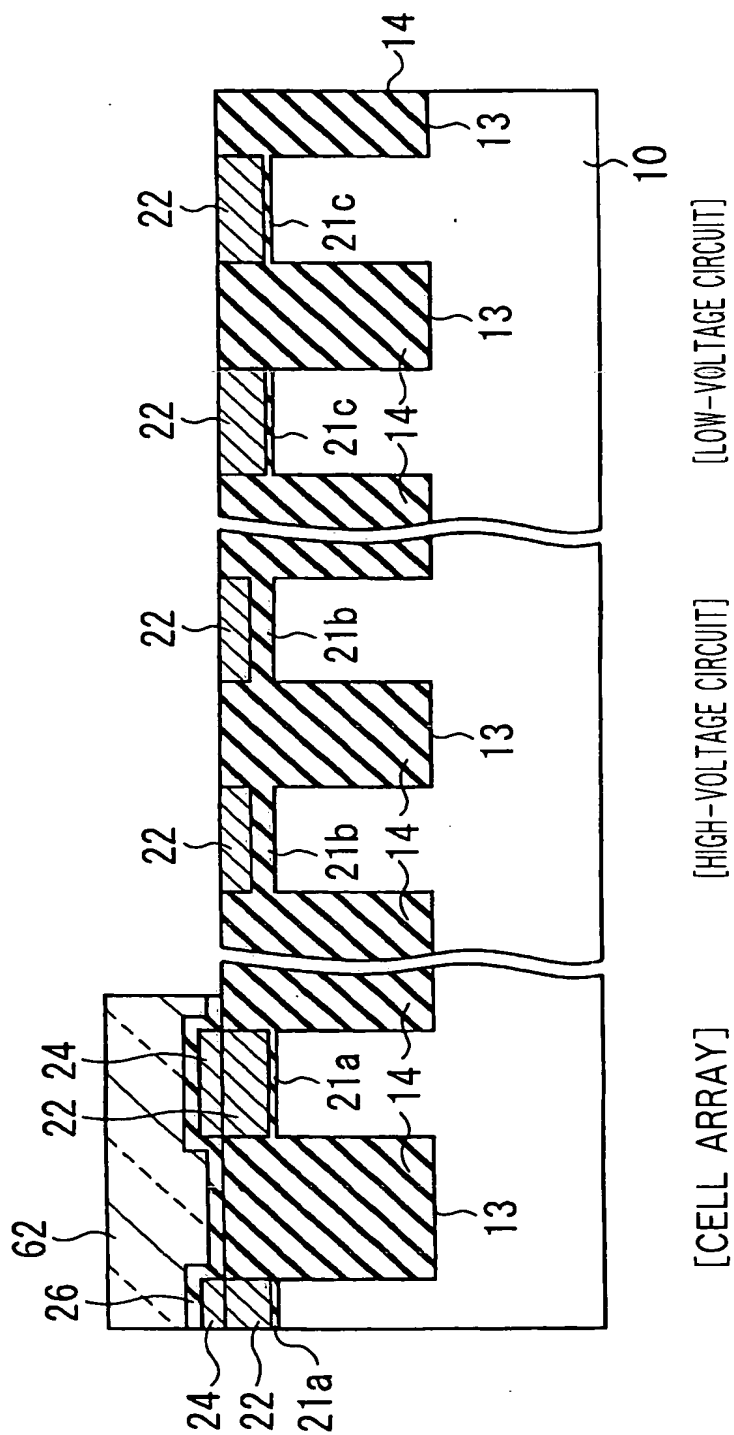


FIG. 33

40/41

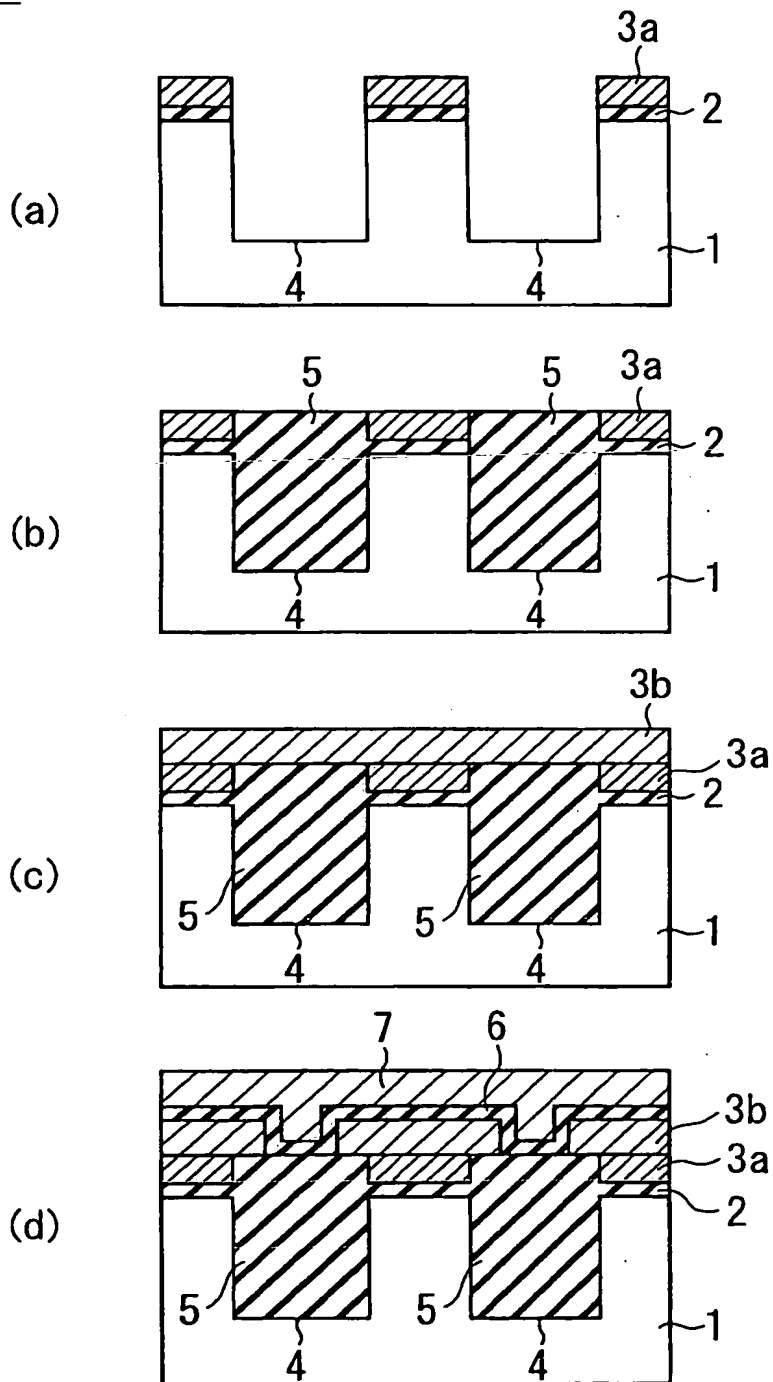


FIG. 35

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41/41

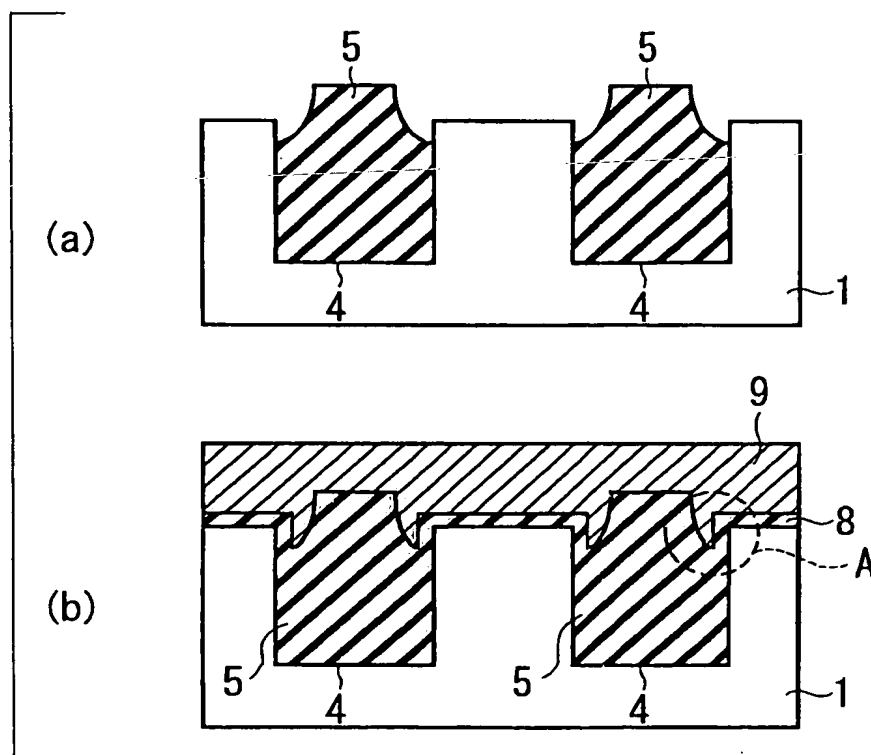


FIG. 36

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